



PCTEST ENGINEERING LABORATORY, INC.

6660-B Dobbin Road, Columbia, MD 21045 USA
Tel. 410.290.6652 / Fax 410.290.6654
http://www.pctestlab.com



HEARING AID COMPATIBILITY

Applicant Name:

Samsung Electronics Co., Ltd.
416 Maetan 3-Dong, Yeongtong-gu, Suwon-si
Gyeonggi-do, 443-742, Republic of Korea

0Y1205

Date of Testing:

June 19-25, 2012

Test Site/Location:

PCTEST Lab, Columbia, MD, USA

Test Report Serial No.:

290740.A3L

FCC ID:

A3LSCHI415

APPLICANT:

SAMSUNG ELECTRONICS CO., LTD.

Scope of Test:

RF Emissions Testing

Application Type:

Certification

FCC Rule Part(s):

§ 20.19(b)

HAC Standard:

ANSI C63.19-2007 §6.3(v), §7.3(v);
CTIA Test Plan for Hearing Aid Compatibility Rev 2.0, April 2010

EUT Type:

Portable Handset

Model(s):

SCH-I415

Tx Frequencies Tested:

824.70 - 848.31 MHz (Cellular CDMA)
1851.25 - 1908.75 MHz (PCS CDMA)
824.20 - 848.80 MHz (GSM 850)
1850.20 - 1909.80 MHz (GSM 1900)

Test Device Serial No.:

Pre-Production Sample [S/N: FCC#3]


C63.19-2007 HAC Category:

M3 (RF EMISSIONS CATEGORY)

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2007 and had been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested and are for North American Bands only.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

PCTEST certifies that no party to this application has been subject to a denial of Federal benefits that includes FCC benefits pursuant to Section 5301 of the Anti-Drug Abuse Act of 1988, 21 U.S.C. 862.


Randy Ortanez
President







FCC ID: A3LSCHI415		HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 1 of 88

TABLE OF CONTENTS

1.	INTRODUCTION	3
2.	TEST SITE LOCATION	4
3.	EUT DESCRIPTION	5
4.	ANSI/IEEE C63.19 PERFORMANCE CATEGORIES	6
5.	SYSTEM SPECIFICATIONS	7
6.	TEST PROCEDURE	13
7.	SYSTEM CHECK	15
8.	MODULATION FACTOR	18
9.	FCC 3G MEASUREMENTS	21
10.	OVERALL MEASUREMENT SUMMARY	23
11.	EQUIPMENT LIST	27
12.	MEASUREMENT UNCERTAINTY	28
13.	TEST DATA	29
14.	CALIBRATION CERTIFICATES	46
15.	CONCLUSION	83
16.	REFERENCES	84
17.	TEST PHOTOGRAPHS	86

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 2 of 88	

1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-8658¹ to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- RF Magnetic-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:



- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.



Figure 1-1 Hearing Aid *in-vitu*

¹ FCC Rule & Order, WT Docket 01-309 RM-8658

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 3 of 88

2. TEST SITE LOCATION

2.1 INTRODUCTION

The map at the right shows the location of the PCTEST LABORATORY in Columbia, Maryland. It is in proximity to the FCC Laboratory, the Baltimore-Washington International (BWI) airport, the city of Baltimore and Washington, DC (See Figure 2).

These measurement tests were conducted at the PCTEST Engineering Laboratory, Inc. facility in New Concept Business Park, Guilford Industrial Park, Columbia, Maryland. The site address is 6660-B Dobbin Road, Columbia, MD 21045. The test site is one of the highest points in the Columbia area with an elevation of 390 feet above mean sea level. The site coordinates are 39° 11'15" N latitude and 76° 49' 38" W longitude. The facility is 1.5 miles North of the FCC laboratory, and the ambient signal and ambient signal strength are approximately equal to those of the FCC laboratory. There are no FM or TV transmitters within 15 miles of the site. The detailed description of the measurement facility was found to be in compliance with the requirements of § 2.948 according to ANSI C63.4 on January 27, 2006 and Industry Canada.





Figure 2-1
Map of the Greater Baltimore and Metropolitan Washington D.C. area

2.2 Test Facility / Accreditations:

Measurements were performed at an independent accredited PCTEST Engineering Lab located in Columbia, MD 21045, U.S.A.



- PCTEST Lab is accredited to ISO 17025-2005 by the American Association for Laboratory Accreditation (A2LA) in Specific Absorption Rate (SAR) testing, Hearing-Aid Compatibility (HAC), CTIA Test Plans, and wireless testing for FCC and Industry Canada Rules.
- PCTEST Lab is accredited to ISO 17025 by U.S. National Institute of Standards and Technology (NIST) under the National Voluntary Laboratory Accreditation Program (NVLAP Lab code: 100431-0) in EMC, FCC and Telecommunications.
- PCTEST facility is an FCC registered (PCTEST Reg. No. 90864) test facility with the site description report on file and has met all the requirements specified in Section 2.948 of the FCC Rules and Industry Canada (IC-2451).
- PCTEST Lab is a recognized U.S. Conformity Assessment Body (CAB) in EMC and R&TTE (n.b. 0982) under the U.S.-EU Mutual Recognition Agreement (MRA).
- PCTEST TCB is a Telecommunication Certification Body (TCB) accredited to ISO/IEC Guide 65 by the American National Standards Institute (ANSI) in all scopes of FCC Rules and all Industry Canada Standards (RSS).
- PCTEST facility is an IC registered (IC-2451) test laboratory with the site description on file at Industry Canada.
- PCTEST is a CTIA Authorized Test Laboratory (CATL) for AMPS and CDMA, and EvDO mobile phones.
- PCTEST is a CTIA Authorized Test Laboratory (CATL) for Over-the-Air (OTA) Antenna Performance testing for AMPS, CDMA, GSM, GPRS, EGPRS, UMTS (W-CDMA), CDMA 1xEVDO Data, CDMA 1xRTT Data.

FCC ID: A3LSCHI415	 PCTEST <small>ENGINEERING LABORATORY, INC.</small>	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 4 of 88	

3. EUT DESCRIPTION



FCC ID: A3LSCHI415
 Manufacturer: Samsung Electronics Co., Ltd.
 416 Maetan 3-Dong, Yeongtong-gu, Suwon-si
 Gyeonggi-do, 443-742, Republic of Korea

Model(s): SCH-I415
 Serial Number: FCC#3
 Tx Frequencies Tested: 824.70 - 848.31 MHz (Cellular CDMA)
 1851.25 - 1908.75 MHz (PCS CDMA)
 824.20 - 848.80 MHz (GSM 850)
 1850.20 - 1909.80 MHz (GSM 1900)

Antenna Configurations: Internal Antenna
 Maximum Conducted Power (HAC): 24.46 dBm (Cell. CDMA), 24.71 dBm (PCS CDMA),
 32.46 dBm (GSM 850), 30.01 dBm (GSM 1900)
 HAC Test Configurations: Cell. CDMA, 1013, 384, 777, BT Off, WLAN Off, LTE Off
 PCS CDMA, 25, 600, 1175, BT Off, WLAN Off, LTE Off
 GSM 850, 128, 190, 251, BT Off, WLAN Off, LTE Off
 GSM 1900, 512, 661, 810, BT Off, WLAN Off, LTE Off

EUT Type: Portable Handset

Air-Interface	Band (MHz)	Type	C63.19/tested	Simultaneous Transmissions (Not to be tested)	Reduced power 20.19 (c)(1)	Voice Over Digital Transport (Data)
GSM	850	Voice	Yes	Yes: BT or WIFI	N/A	N/A
	1900					Yes.
CDMA	GPRS/EDGE	Data	N/A	N/A		
	850	Voice	Yes	Yes: LTE, BT or WIFI	N/A	N/A
	1900					Yes
	EVDO	Data	N/A			
LTE (Band 13)	782	Data	N/A	Yes: CDMA, BT or WIFI	N/A	Yes
BT	2450	Data	N/A	Yes: GSM, CDMA or LTE	N/A	N/A
WIFI	2450	Data	N/A	Yes: GSM, CDMA or LTE	N/A	Yes
	5200					
	5300					
	5500					
	5800					

NOTE: HAC Rating was not based on concurrent voice and data modes. Standalone mode was found to represent worst case rating for M rating.

Table 3: A3LSCHI415 Air Interfaces

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 5 of 88

4. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES



I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters	
Near field Category	E-field emissions CW dB(V/m)	H-field emissions CW dB(A/m)
f < 960 MHz		
M1	56 to 61 + 0.5 x AWF	5.6 to 10.6 +0.5 x AWF
M2	51 to 56 + 0.5 x AWF	0.6 to 5.6 +0.5 x AWF
M3	46 to 51 + 0.5 x AWF	-4.4 to 0.6 +0.5 x AWF
M4	< 46 + 0.5 x AWF	< -4.4 + 0.5 x AWF
f > 960 MHz		
M1	46 to 51 + 0.5 x AWF	-4.4 to 0.6 +0.5 x AWF
M2	41 to 46 + 0.5 x AWF	-9.4 to -4.4 +0.5 x AWF
M3	36 to 41 + 0.5 x AWF	-14.4 to -9.4 +0.5 x AWF
M4	< 36 + 0.5 x AWF	< -14.4 + 0.5 x AWF
Table 4-1 Hearing aid and WD near-field categories as defined in ANSI C63.19-2007		

II. ARTICULATION WEIGHTING FACTOR (AWF)

Standard	Technology	Articulation Weighing Factor (AWF)
T1/T1P1/3GPP	UMTS (WCDMA)	0
TIA/EIA/IS-2000	CDMA	0
iDEN ^T	TDMA (22 and 11 Hz)	0
J-STD-007	GSM (217 Hz)	-5
Table 4-2 Articulation Weighting Factors		

FCC ID: A3LSCHI415		HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 6 of 88	

5. SYSTEM SPECIFICATIONS

ER3DV6 E-Field Probe Description

Construction:	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges
Calibration:	In air from 100 MHz to 3.0 GHz (absolute accuracy $\pm 6.0\%$, $k=2$)
Frequency:	100 MHz to > 6 GHz; Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis) ± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m (M3 or better device readings fall well below diode compression point)
Linearity:	± 0.2 dB
Dimensions	Overall length: 330 mm (Tip: 16 mm) Tip diameter: 8 mm (Body: 12 mm) Distance from probe tip to dipole centers: 2.5 mm



Figure 5-1
E-field Free-space Probe

H3DV6 H-Field Probe Description

Construction:	Three concentric loop sensors with 3.8 mm loop diameters Resistively loaded detector diodes for linear response Built-in shielding against static charges
Frequency:	200 MHz to 3 GHz (absolute accuracy $\pm 6.0\%$, $k=2$); Output linearized
Directivity:	± 0.25 dB (spherical isotropy error)
Dynamic Range:	10 mA/m to 2 A/m at 1 GHz (M3 or better device readings fall well below diode compression point)
Dimensions:	Overall length: 330 mm (Tip: 40 mm) Tip diameter: 6 mm (Body: 12 mm) Distance from probe tip to dipole centers: 3 mm
E-Field Interference:	< 10% at 3 GHz (for plane wave)





Figure 5-2
H-Field Free-space Probe

Probe Tip Description

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

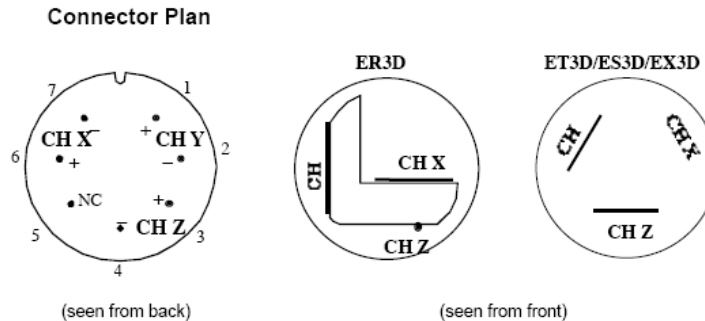
Magnetic field sensors are measuring the integral of the H-field across their sensor area surrounded by the loop. They are calibrated in a precise, homogeneous field. When measuring a gradient field, the result will be very close to the field in the center of the loop which is equivalent to the value of a homogeneous field equivalent to the center value. But it will be different from the field at the border of the loop.

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 7 of 88	

Consequently, two sensors with different loop diameters - both calibrated ideally - would give different results when measuring from the edge of the probe sensor elements. The behavior for electrically small E-field sensors is equivalent.

The magnetic field loops of the H3D probes are concentric, with the center 3mm from the tip for H3DV6. Their radius is 1.9mm.

The electric field probes have a more irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement"). Their geometric center is at 2.5mm from the tip, and the element ends are 1.1mm closer to the tip.



The antistatic shielding inside the probe is connected to the probe connector case.

Instrumentation Chain

Equation 1

Conversion of Connector Voltage u_i to E-Field E_i

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF) / (DCP)}{Norm_i \cdot ConvF}}$$

whereby

- E_i : electric field in V/m
- u_i : voltage of channel i at the connector in μV
- $Norm_i$: sensitivity of channel i in $\mu V / (V/m)^2$
- $ConvF$: enhancement factor in liquid (ConvF=1 for Air)
- DCP : diode compression point in μV
- CF : signal crest factor (peak power/average power)

Conditions of Calibration

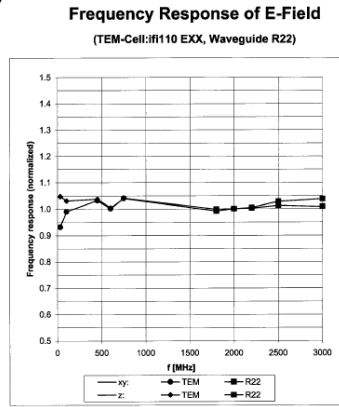


- Please note:
- a lower input impedance of the amplifier will result in different sensitivity factors $Norm_i$ and DCP
 - larger bias currents will cause higher offset

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 8 of 88

Probe Response to Frequency

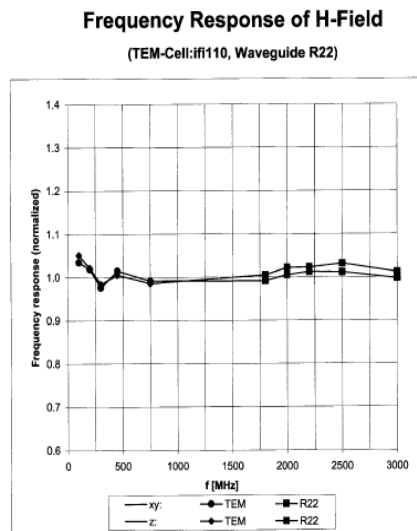
The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).



Uncertainty of Frequency Response of E-field: $\pm 6.3\%$ ($k=2$)

Figure 5-3 E-Field Probe Frequency Response

H-field sensors have a frequency dependent sensitivity which is evaluated for a series of frequencies also visible in the probe calibration certificate. The calibration factors result from a fitting algorithm. The proper conversion is calculated by the DASY4 software depending on the frequency setting in the procedure. See below for H-field frequency response:



Uncertainty of Frequency Response of E-field: $\pm 6.3\%$ ($k=2$)

Figure 5-4 H-Field Probe Frequency Response

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 9 of 88

Conversion to Peak

Peak is defined as Peak Envelope Power. All raw measurements from the HAC measurement system are RMS values. The DASY4 system incorporates the crest factor of the signal in the computation of the RMS values (See Equation 1). Although the software also has capability to estimate the peak field by applying a square root of crest factor value to the readings, the probe modulation factor was applied manually instead per C63.19 in the measurement tables in this report. The equation to convert the raw measurements in the data tables are:

$$\text{Peak Field} = 20 \cdot \log (\text{Raw} \cdot \text{PMF})$$

Where:

Peak Field = Peak field (in dBV/m or dBA/m)

Raw = Raw field measurement from the measurement system (in V/m or A/m).

PMF = Probe Modulation Factor (in linear units).

SPEAG Robotic System



E-field and H-field measurements are performed using the DASY4 automated dosimetric assessment system. The DASY4 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Pentium 4 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



Figure 5-5
SPEAG Robotic System

System Hardware

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the Gateway Pentium 4 2.53 GHz computer with Windows XP system and RF Measurement Software DASY4 v4.5 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 10 of 88

System Electronics

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.





Figure 5-6
SPEAG Robotic System Diagram

DASY4 Instrumentation Chain

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$V_i = U_i + U_i^2 \cdot \frac{cf}{dcp_i}$$

with V_i	= compensated signal of channel i	(i = x, y, z)
U_i	= input signal of channel i	(i = x, y, z)
cf	= crest factor of exciting field	(DASY parameter)
dcp_i	= diode compression point	(DASY parameter)

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 11 of 88

From the compensated input signals the primary field data for each channel can be evaluated:

$$\text{E - fieldprobes : } E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

$$\text{H - fieldprobes : } H_i = \sqrt{V_i} \cdot \frac{a_{i0} + a_{i1}f + a_{i2}f^2}{f}$$

with V_i = compensated signal of channel i (i = x, y, z)
 $Norm_i$ = sensor sensitivity of channel i (i = x, y, z)
 $\mu\text{V}/(\text{V/m})^2$ for E-field Probes
 $ConvF$ = sensitivity enhancement in solution
 a_{ij} = sensor sensitivity factors for H-field probes
 f = carrier frequency [GHz]
 E_i = electric field strength of channel i in V/m
 H_i = magnetic field strength of channel i in A/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):



$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500 ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500 ms and a probe response time of <5 ms. In the current implementation, DASY4 waits longer than 100 ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 12 of 88	

6. TEST PROCEDURE

I. RF EMISSIONS

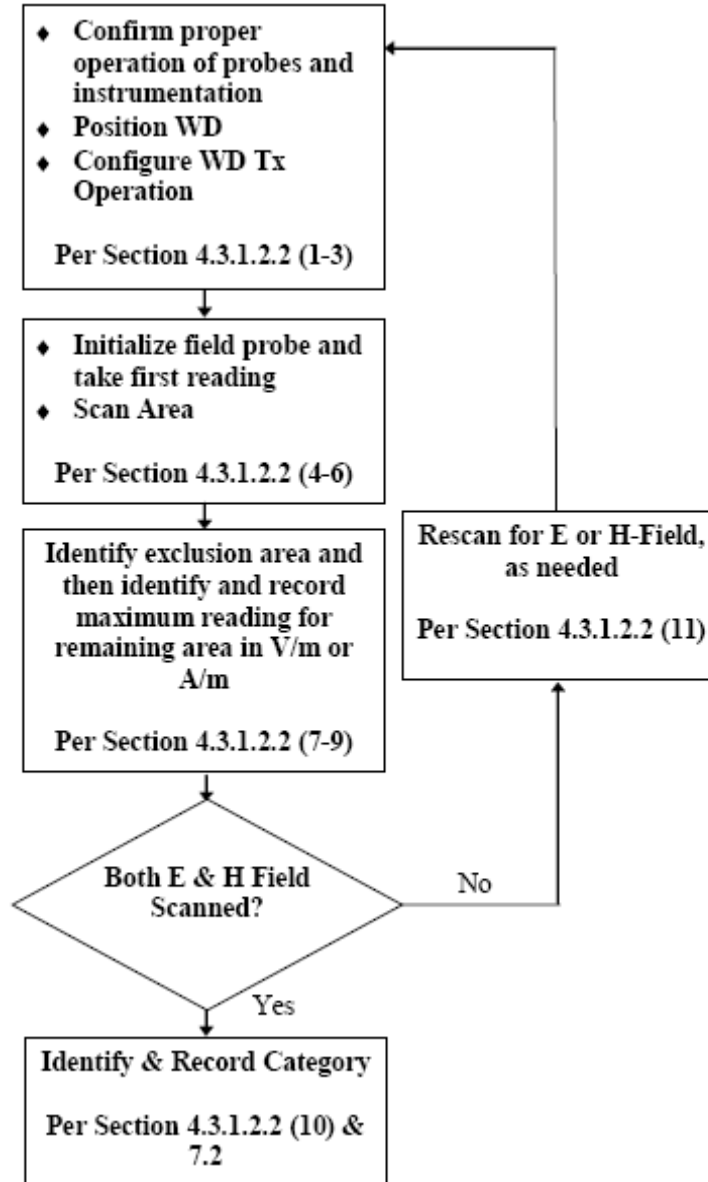


Figure 6-1
WD Near-Field Emissions Flow Chart

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 13 of 88

Test Setup

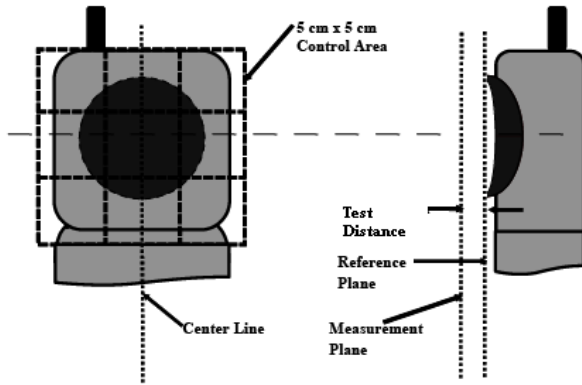


Figure 6-2

E/H-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

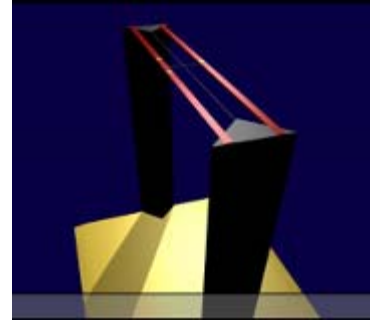




Figure 6-3
HAC Phantom

RF Emissions Test Procedure:

The following illustrate a typical RF emissions test scan over a wireless communications device:

1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
6. The measurement system measured the field strength at the reference location.
7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
8. The system performed a drift evaluation by measuring the field at the reference location.
9. Steps 1-8 were done for both the E and H-Field measurements.

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 14 of 88

7. SYSTEM CHECK

I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power $P = 100\text{mW RMS}$ (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 1 cm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:

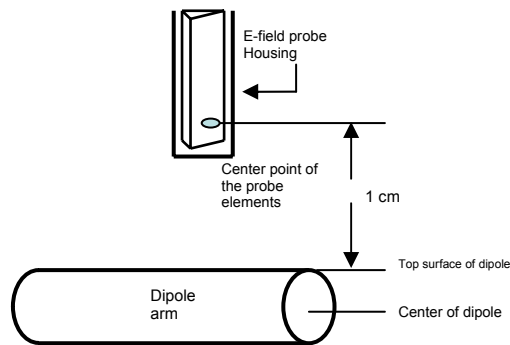


Figure 7-1
Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device (e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (i.e. - 20dBm) RMS after adjustment for any mismatch.



II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned with both E-field and H-field probes and the maximum values for each were recorded.

Measurement of CW

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (see

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 15 of 88

manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

RF power was recorded using both an average and a peak power reading meter.

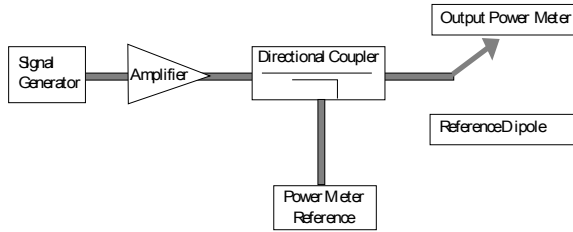


Figure 7-2
Setup for Desired Output Power to Dipole

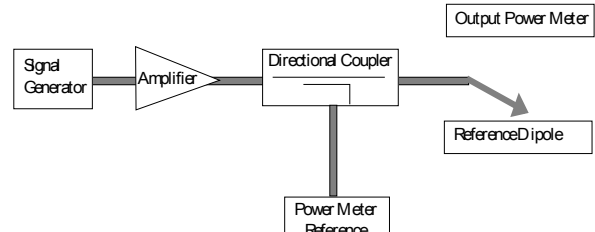


Figure 7-3
Setup to Dipole

Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 7-3.

The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



Figure 7-4

2-D Raw Data from scan along dipole axis

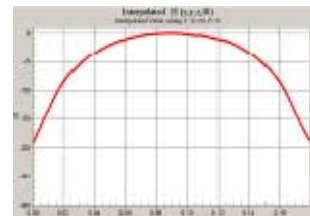


Figure 7-5

2-D Interpolated points from scan along dipole axis

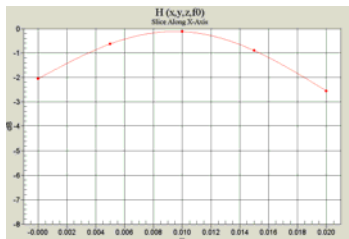


Figure 7-6

2-D Raw Data from scan along transverse axis

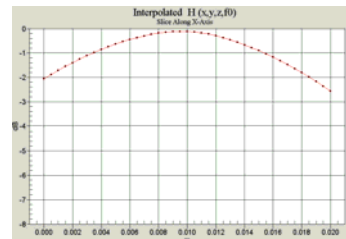


Figure 7-7

2-D Interpolated points from scan along transverse axis

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 16 of 88

III. System Check Results

Validation Results

Frequency (MHz)	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
835	1003	20.0	164.9	166.0	-0.7%
1880	1137	20.0	138.1	136.8	1.0%
Frequency (MHz)	Dipole S/N	Input Power (dBm)	H-field Result (A/m)	Target Field (A/m)	% Deviation
835	1003	20.0	0.472	0.458	3.1%
1880	1137	20.0	0.439	0.460	-4.6%

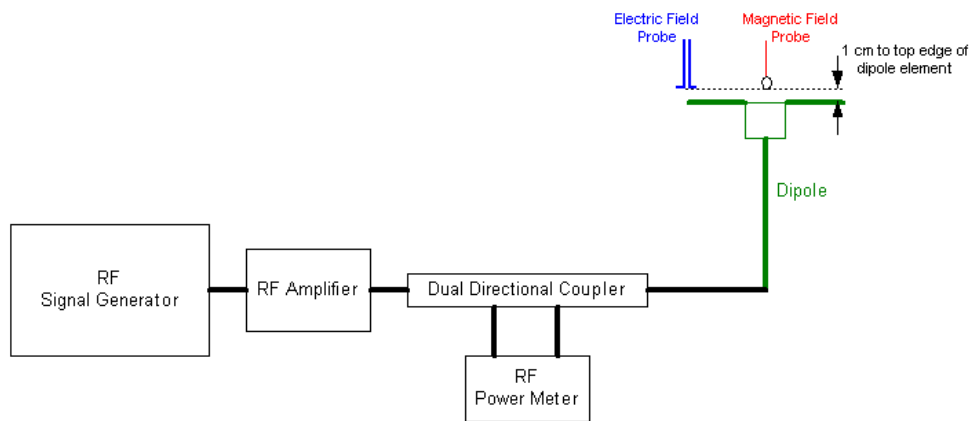


Figure 7-8
System Check Setup

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 17 of 88

8. MODULATION FACTOR

A calibration was made of the modulation response of the probe and its instrumentation chain. This calibration was performed with the field probe, attached to its instrumentation. The response of the probe system to a CW field at the frequency of interest is compared to its response to a modulated signal with equal peak amplitude to that of a CW signal. The field level of the test signals are ensured to be more than 10 dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated reading was applied to the DUT measurements.

All voice modes for this device have been investigated in this section of the report. According to the FCC 3G Measurement Procedures, May 2006 for RF Emissions, variations in peak field and power readings.

This was done using the following procedure:

1. The probe was illuminated with a CW signal at the intended measurement frequency and wireless device power.
2. The probe was positioned at the field maxima over the dipole antenna (determined after an area scan over the dipole) illuminated with the CW signal.
3. The reading of the probe measurement system of the CW signal at the maximum point was recorded.
4. Using a Spectrum Analyzer, the modulated signal adjusted with the same peak level of the CW signal was determined.
5. The probe measurement system reading was recorded with the modulated signal. The appropriate system crest factors for the modulation type were configured in the software to the system measurements.
6. The ratio of the CW reading to modulated signal reading is the probe modulation factor (PMF) for the modulation and field probe combination. This was repeated for 80% AM.
7. Steps 1-6 were repeated at all frequency bands and for both E and H field probes.

The modulation factors obtained were applied to readings taken of the actual wireless device, in order to obtain an accurate peak field reading using the formula:

$$\text{Peak} = 20 \cdot \log (\text{Raw} \cdot \text{PMF})$$

This method correlates well with the modulation using the DUT in the alternative substitution method. See below for correlation of signal:

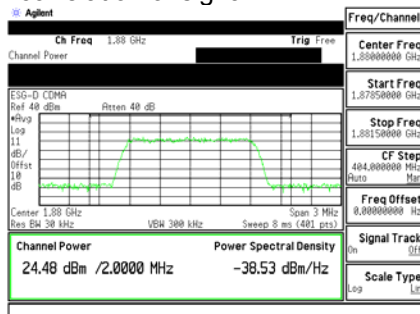


Figure 8-1
Signal Generator Modulated Signal

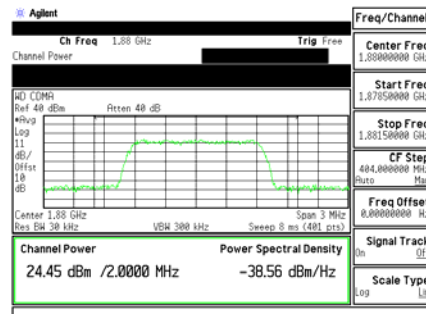


Figure 8-2
Wireless Device Modulated Signal

FCC ID: A3LSCHI415	PCTEST <small>ENGINEERING LABORATORY, INC.</small>	HAC (RF EMISSIONS) TEST REPORT	
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Reviewed by: Quality Manager
			Page 18 of 88

I. CDMA Modulation Factors

f (MHz)	Protocol	E-Field (V/m)	H-Field (A/m)	E-Field Modulation Factor	H-Field Modulation Factor
835	AM	204.50	0.5971	1.411	1.326
835	CDMA	311.00	0.9799	0.928	0.808
835	CW	288.60	0.7915		
1880	AM	155.40	0.6561	1.445	1.501
1880	CDMA	226.80	1.2010	0.990	0.820
1880	CW	224.50	0.9846		
850	CDMA/SO3	46.28	0.2267	3.025	2.895
850	CW	140.00	0.6562		
1880	CDMA/SO3	58.27	0.1999	3.151	2.853
1880	CW	183.60	0.5704		

Figure 8-3
CDMA Modulation Factors

FCC 3G Note: "CDMA" represents RC1/SO55 mode, while "CDMA/SO3" represents RC1/SO3 mode. Other modes were investigated and were within 0.25 dB of the RC1/SO55 configuration per Table 9-3.

CW and Modulated Signal Zero-Span plots:

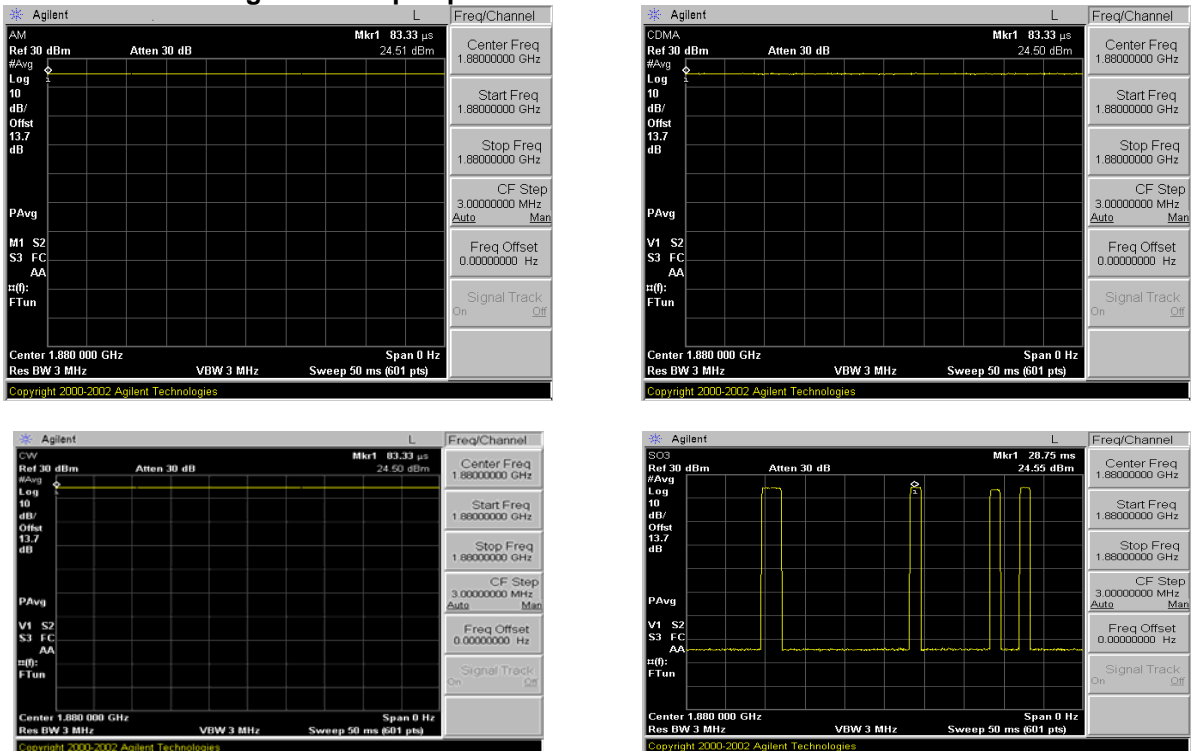


Figure 8-4 Zero-Span Plots

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	LAMBDA	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 19 of 88

II. GSM Modulation Factors

f (MHz)	Protocol	E-Field (V/m)	H-Field (A/m)	E-Field Modulation Factor	H-Field Modulation Factor
835	AM	629.3	2.212	1.290	0.910
835	GSM	287	1.033	2.829	1.948
835	CW	811.8	2.012		
1880	AM	390.8	1.215	1.319	1.115
1880	GSM	184.8	0.5843	2.790	2.319
1880	CW	515.6	1.355		

Figure 8-5
GSM Modulation Factors

Spectrum Analyzer Plots of ESG-D Signal used for PMF measurements:

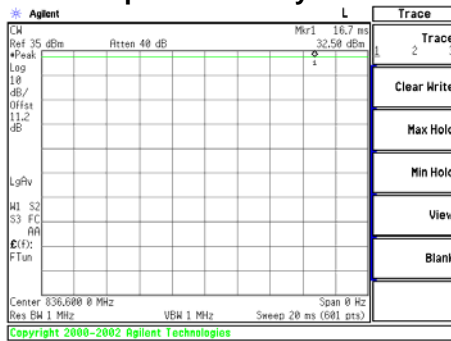


Figure 8-6 GSM850 CW Signal

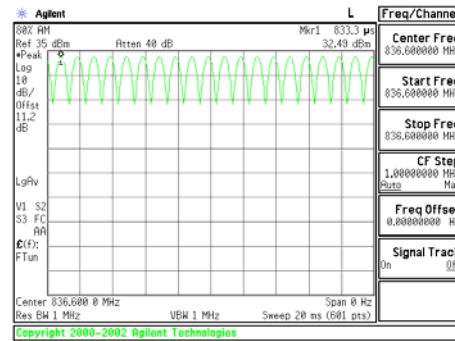


Figure 8-7 GSM850 80% AM Signal

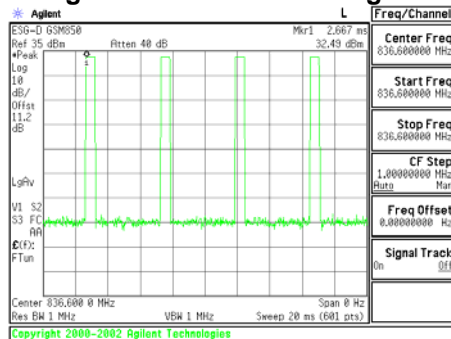


Figure 8-8 GSM850 Signal

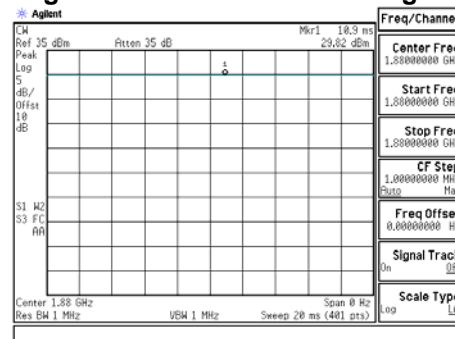


Figure 8-9 GSM1900 CW Signal

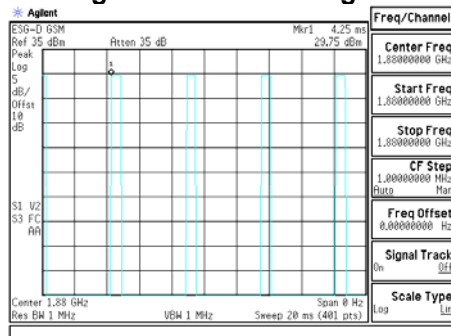


Figure 8-10 GSM1900 Signal

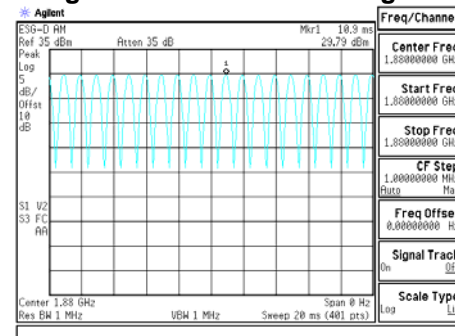


Figure 8-11 GSM1900 80% AM Signal

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 20 of 88

9. FCC 3G MEASUREMENTS

Power measurements were performed using a base station simulator under digital average power.

I. Procedures Used to Establish RF Signal for HAC Testing

The handset was placed into a simulated call using a base station simulator in a shielded chamber. Such test signals offer a consistent means for testing HAC and are recommended for evaluating HAC. Measurements were taken with a fully charged battery. In order to verify that the device was tested and maintained at full power, this was configured with the base station simulator. The HAC measurement software calculates a reference point at the start and end of the test to check for power drifts. If conducted power deviations of more than 5% occurred, the tests were repeated.

II. Conducted RF Output Power Measurements:

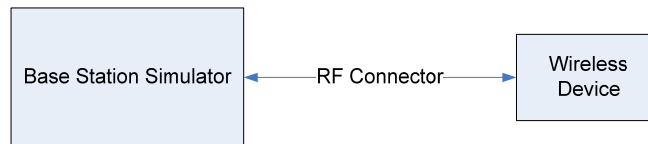


Figure 9-1
Power Measurement Setup

See below for measured conducted power for applicable device modes:

A. CDMA RF Conducted Powers

Band	Channel	SO2 [dBm]	SO2 [dBm]	SO2 [dBm]	SO55 [dBm]	SO55 [dBm]	SO9 [dBm]	SO9 [dBm]	SO3 [dBm]	SO3 [dBm]	SO3 [dBm]
	F-RC	RC1	RC3	RC4	RC1	RC3	RC2	RC5	RC1	RC3	RC4
Cellular	1013	24.34	24.33	24.31	24.44	24.41	24.32	24.33	24.39	24.28	24.32
	384	24.38	24.32	24.29	24.46	24.39	24.34	24.31	24.34	24.29	24.29
	777	42.31	24.29	24.31	24.36	24.33	24.27	24.29	24.31	24.30	24.28
PCS	25	24.53	24.52	24.47	24.61	24.57	24.51	24.51	24.59	24.46	24.47
	600	24.51	24.46	24.48	24.54	24.51	24.53	24.49	24.54	24.44	24.43
	1175	24.66	24.53	24.63	24.61	24.55	24.59	24.49	24.71	24.56	24.56

Table 9-1
CDMA RF Conducted Power Table

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 21 of 88

B. GSM RF Conducted Powers

Band	Channel	GSM [dBm] CS (1 Slot)
Cellular	128	32.25
	190	32.46
	251	32.05
PCS	512	29.92
	661	30.01
	810	29.99



Table 9-2
GSM RF Conducted Power Table

III. Worst-Case Probe Location Measurements

Sample pre-testing of the various CDMA modes was performed at the worst case probe location as part of subset testing justification. Below are RC/SO mode investigation results of the device at the worst-case (maximum) field point location.

Table 9-3
Handset 3G mode variation on RF Emissions

Mode	Channel	Backlight	RC/SO	Scan Center	Time Avg. Field (V/m)	Modulation Factor	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
PCS	600	on	SO3/RC1	Acoustic	7.12	3.151	22.4	27.0	41.0	-13.98	M4	none
PCS	600	off	SO3/RC3	Acoustic	19.92	0.990	19.7	25.9	41.0	-15.10	M4	none
PCS	600	off	SO3/RC4	Acoustic	19.80	0.990	19.6	25.8	41.0	-15.16	M4	none
PCS	600	off	SO55/RC3	Acoustic	19.58	0.990	19.4	25.7	41.0	-15.25	M4	none
PCS	600	off	SO55/RC1	Acoustic	19.65	0.990	19.5	25.8	41.0	-15.22	M4	none
PCS	600	off	SO2/RC1	Acoustic	19.85	0.990	19.6	25.9	41.0	-15.13	M4	none
PCS	600	off	SO2/RC3	Acoustic	19.71	0.990	19.5	25.8	41.0	-15.19	M4	none
PCS	600	off	SO9/RC2	Acoustic	19.66	0.990	19.5	25.8	41.0	-15.22	M4	none
PCS	600	off	SO9/RC5	Acoustic	19.68	0.990	19.5	25.8	41.0	-15.21	M4	none

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 22 of 88

10. OVERALL MEASUREMENT SUMMARY

FCC ID:	A3LSCHI415
Model:	SCH-I415
S/N:	FCC#3

I. E-FIELD EMISSIONS:

Table 10-1
HAC Data Summary for E-field, CDMA RC1/SO3



Band	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Modulation Factor	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
E-field Emissions												
CDMA	1013	off	Acoustic	24.39	17.30	3.025	52.3	34.4	51.0	-16.62	M4	none
CDMA	384	off	Acoustic	24.34	15.36	3.025	46.5	33.3	51.0	-17.66	M4	none
CDMA	777	off	Acoustic	24.31	14.93	3.025	45.2	33.1	51.0	-17.90	M4	none
PCS	25	off	Acoustic	24.59	6.22	3.151	19.6	25.8	41.0	-15.15	M4	none
PCS	600	off	Acoustic	24.54	8.08	3.151	25.5	28.1	41.0	-12.88	M4	none
PCS	1175	off	Acoustic	24.71	6.33	3.151	19.9	26.0	41.0	-15.00	M4	none

Table 10-2
HAC Data Summary for E-field, CDMA RC1/SO55

Band	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Modulation Factor	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
E-field Emissions												
CDMA	1013	off	Acoustic	24.44	48.16	0.928	44.7	33.0	51.0	-18.00	M4	none
CDMA	384	off	Acoustic	24.46	38.19	0.928	35.4	31.0	51.0	-20.01	M4	none
CDMA	777	off	Acoustic	24.36	42.78	0.928	39.7	32.0	51.0	-19.02	M4	none
PCS	25	off	Acoustic	24.61	21.01	0.990	20.8	26.4	41.0	-14.64	M4	none
PCS	600	off	Acoustic	24.54	19.28	0.990	19.1	25.6	41.0	-15.39	M4	none
PCS	1175	off	Acoustic	24.61	17.67	0.990	17.5	24.9	41.0	-16.14	M4	none

Table 10-3
HAC Data Summary for E-field, GSM

Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
E-field Emissions										
GSM850	128	off	Acoustic	32.25	32.32	39.22	48.50	-9.28	M4	none
GSM850	190	off	Acoustic	32.46	46.17	42.32	48.50	-6.18	M4	none
GSM850	251	off	Acoustic	32.05	46.22	42.33	48.50	-6.17	M4	none
GSM1900	512	off	Acoustic	29.92	17.04	33.54	38.50	-4.96	M3	none
GSM1900	661	off	Acoustic	30.01	18.68	34.34	38.50	-4.16	M3	none
GSM1900	810	off	Acoustic	29.99	17.25	33.65	38.50	-4.85	M3	none

FCC ID: A3LSCHI415	 PCTEST <small>ENGINEERING LABORATORY, INC.</small>	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 23 of 88	

FCC ID:	A3LSCHI415
Model:	SCH-I415
S/N:	FCC#3

II. H-FIELD EMISSIONS:

**Table 10-4
HAC Data Summary for H-field, CDMA RC1/SO3**



Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (A/m)	Modulation Factor	Peak Field (A/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
H-field Emissions												
CDMA	1013	off	Acoustic	24.39	0.0311	2.895	0.090	-20.9	0.6	-21.50	M4	none
CDMA	384	off	Acoustic	24.34	0.0399	2.895	0.115	-18.8	0.6	-19.36	M4	none
CDMA	777	off	Acoustic	24.31	0.0296	2.895	0.086	-21.4	0.6	-21.96	M4	none
PCS	25	off	Acoustic	24.59	0.0179	2.853	0.051	-25.8	-9.4	-16.42	M4	none
PCS	600	off	Acoustic	24.54	0.0171	2.853	0.049	-26.2	-9.4	-16.84	M4	none
PCS	1175	off	Acoustic	24.71	0.0178	2.853	0.051	-25.9	-9.4	-16.46	M4	none

**Table 10-5
HAC Data Summary for H-field, CDMA RC1/SO55**

Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (A/m)	Modulation Factor	Peak Field (A/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
H-field Emissions												
CDMA	1013	off	Acoustic	24.44	0.0857	0.808	0.069	-23.2	0.6	-23.79	M4	none
CDMA	384	off	Acoustic	24.46	0.0940	0.808	0.076	-22.4	0.6	-22.99	M4	none
CDMA	777	off	Acoustic	24.36	0.0820	0.808	0.066	-23.6	0.6	-24.17	M4	none
PCS	25	off	Acoustic	24.61	0.0424	0.820	0.035	-29.2	-9.4	-19.78	M4	none
PCS	600	off	Acoustic	24.54	0.0475	0.820	0.039	-28.2	-9.4	-18.80	M4	none
PCS	1175	off	Acoustic	24.61	0.0466	0.820	0.038	-28.4	-9.4	-18.96	M4	none

**Table 10-6
HAC Data Summary for H-field, GSM**

Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (A/m)	Modulation Factor	Peak Field (A/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
H-field Emissions												
GSM850	128	off	Acoustic	32.25	0.0655	1.948	0.128	-17.9	-1.9	-15.98	M4	none
GSM850	190	off	Acoustic	32.46	0.0993	1.948	0.193	-14.3	-1.9	-12.37	M4	none
GSM850	251	off	Acoustic	32.05	0.0885	1.948	0.172	-15.3	-1.9	-13.37	M4	none
GSM1900	512	off	Acoustic	29.92	0.0487	2.319	0.113	-18.9	-11.9	-7.04	M4	none
GSM1900	661	off	Acoustic	30.01	0.0416	2.319	0.096	-20.3	-11.9	-8.42	M4	none
GSM1900	810	off	Acoustic	29.99	0.0401	2.319	0.093	-20.6	-11.9	-8.72	M4	none

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 24 of 88	

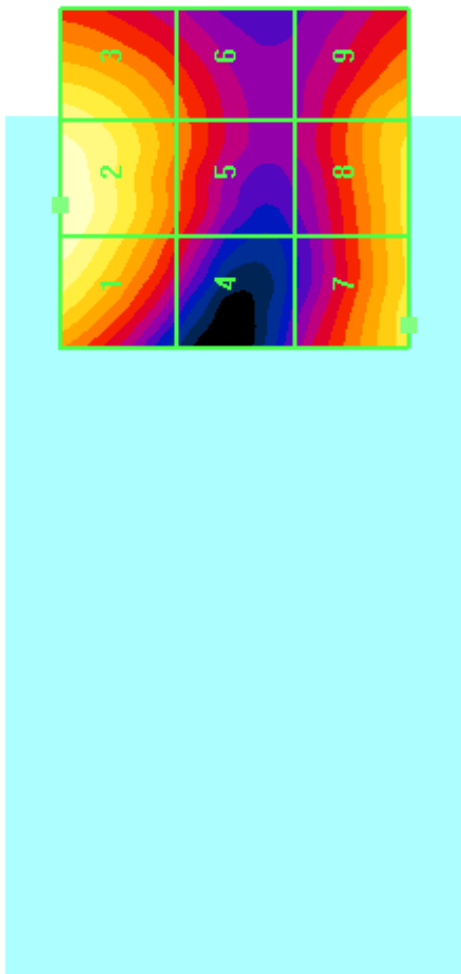


Figure 10-1
Sample E-field Scan Overlay

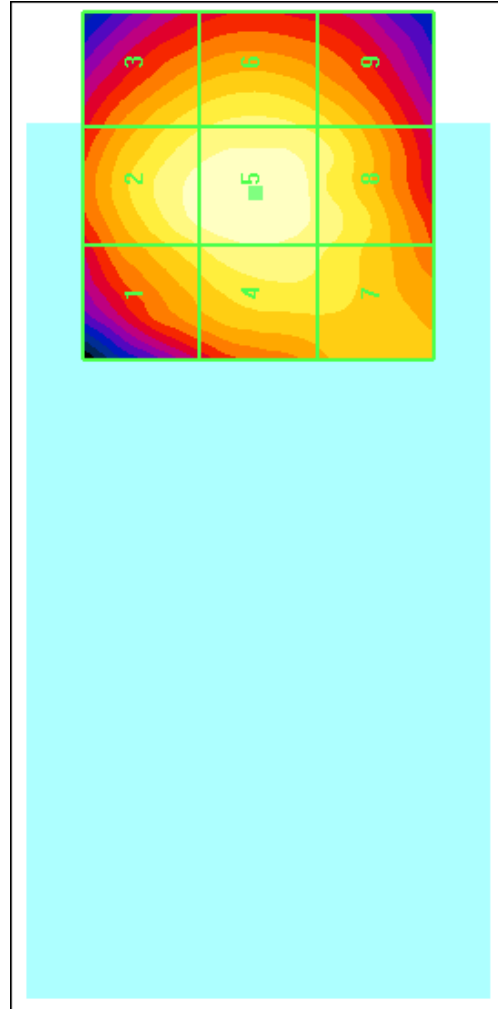




Figure 10-2
Sample H-field Scan Overlay

Note: See Test Setup Photographs for actual WD overlay

FCC ID: A3LSCHI415		HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 25 of 88	

FCC ID:	A3LSCHI415
Model:	SCH-I415
S/N:	FCC#3

III. Worst-case Configuration Evaluation

Table 10-7
Peak Reading 360° Probe Rotation at Azimuth axis

Mode	Channel	Backlight	Scan Center	Time Avg. Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT
Probe Rotation at Worst-Case								
GSM1900	661	off	Acoustic	19.32	34.63	38.50	-3.87	M3

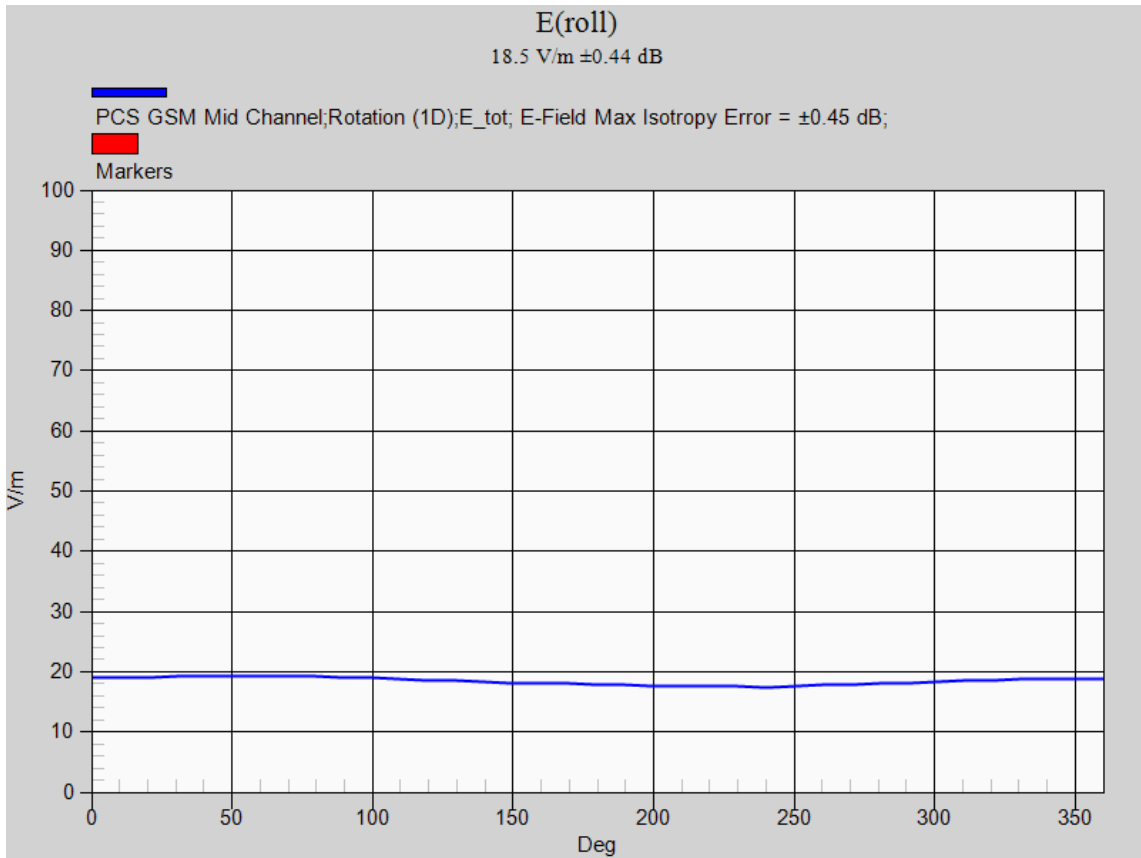


Figure 10-3
Worst-Case Probe Rotation about Azimuth axis

* Note: Locations of probe rotation (with and without exclusions) are shown in Figure 10-1 or Figure 10-2 denoted by the green square markers.

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 26 of 88	



11. EQUIPMENT LIST

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent E	4407B	ESA Spectrum Analyzer	4/3/2012	Annual	4/3/2013	US39210313
Agilent	E4432B	ESG-D Series Signal Generator	3/15/2012	Annual	3/15/2013	US40053896
Agilent	E5515C	Wireless Communications Test Set	10/10/2011	Annual	10/10/2012	GB46110872
Agilent	E5515C	Wireless Communications Test Set	10/14/2011	Annual	10/14/2012	GB41450275
Agilent	E5515C	Wireless Communications Test Set	10/20/2011	Annual	10/20/2012	GB46310798
Agilent	E5515C	Wireless Communications Test Set	2/9/2012	Annual	2/9/2013	GB43460554
Agilent	E5515C	Wireless Communications Test Set	2/12/2012	Annual	2/12/2013	GB45360985
Agilent	E5515C	Wireless Communications Test Set	2/14/2012	Annual	2/14/2013	GB43304447
Agilent	E5515C	Wireless Communications Test Set	2/14/2012	Annual	2/14/2013	GB43163447
Agilent E	5515C	Wireless Communications Tester	4/4/2012	Annual	4/4/2013	US41140256
Anritsu MA	2481A	Power Sensor	2/14/2012	Annual	2/14/2013	3681
Control Company	36934-158	Wall-Mounted Thermometer	1/4/2012	Biennial	1/4/2014	122014497
Control Company	36934-158	Wall-Mounted Thermometer	1/4/2012	Biennial	1/4/2014	122014488
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Rohde & Schwarz	CMU200	Base Station Simulator	5/22/2012	Annual	5/22/2013	109892
Rohde & Schwarz	NRVD	Dual Channel Power Meter	4/8/2011	Biennial	4/8/2013	101695
Seekonk N	C-100	Torque Wrench (8" lb) 1	1/29/2011	Triennial	11/29/2014	21053
SPEAG D	AE4	Dasy Data Acquisition Electronics	2/20/2012	Annual	2/20/2013	649
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	2/9/2011	Biennial	2/9/2013	1137
SPEAG	CD835V3	Freespace 835 MHz Dipole	2/8/2011	Biennial	2/8/2013	1003
SPEAG	ER3DV6	Freespace E-field Probe	1/20/2012	Annual	1/20/2013	2353
SPEAG	H3DV6	Freespace H-field Probe	1/20/2012	Annual	1/20/2013	6207

Table 11-1
Equipment List

Calibration traceable to the National Institute of Standards and Technology (NIST)

***Note: CBT (Calibrated Before Testing).** Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 27 of 88	

12. MEASUREMENT UNCERTAINTY



Wireless Communications Device Near-Field Measurement								
Uncertainty Estimation								
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Ci (H)	Unc. (dB)	Notes/Comments
Measurement System								
RF System Reflections	0.50	Tolerance	N	1.00	1	1	0.50	Refl. < -20 dB
Field Probe Calibration	0.21	Tolerance	N	1.00	1	1	0.21	
Field Probe Isotropy	0.01	Tolerance	N	1.00	1	1	0.01	
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	1	0.14	
Field Probe Linearity	0.013	Tolerance	N	1.00	1	1	0.01	
Probe Modulation Factor	0.270	Accuracy	R	1.73	1	1	0.16	
Boundary Effects	0.105	Accuracy	R	1.73	1	1	0.06	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.670	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	1	0.670	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	1	0.03	*
Resolution to 2mm error	0.210	Tolerance	N	1.00	1	1	0.21	
System Detection Limit	0.05	Tolerance	R	1.73	1	1	0.03	*
Readout Electronics	0.015	Tolerance	N	1.00	1	1	0.02	*
Integration Time	0.11	Tolerance	R	1.73	1	1	0.06	*
Response Time	0.033	Tolerance	R	1.73	1	1	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	1	1	0.06	*
System Repeatability (Field x 2=power)	0.17	Tolerance	N	1.00	1	1	0.17	
Test Sample Related								
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	1	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	1	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	1	0.06	*
Power Drift	0.21	Tolerance	R	1.73	1	1	0.12	
<i>Combined Standard Uncertainty (k=1)</i>							0.66	16.5%
<i>Expanded Uncertainty [95% confidence] (k=2)</i>							1.33	32.3%
<i>Expanded Uncertainty [95% confidence] on Field</i>							0.66	16.2%

Table 12-1
Uncertainty Estimation Table

Notes:



1. Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81 and NIST Tech Note 1297 and UKAS M3003.
2. * Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 28 of 88	

13. TEST DATA

See following Attached Pages for Test Data.

FCC ID: A3LSCHI415		HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 29 of 88



PCTEST Hearing-Aid Compatibility Facility

DUT: CD835V3 - SN1003

Type: CD835V3
Serial: 1003

Communication System: CW; Frequency: 835 MHz;

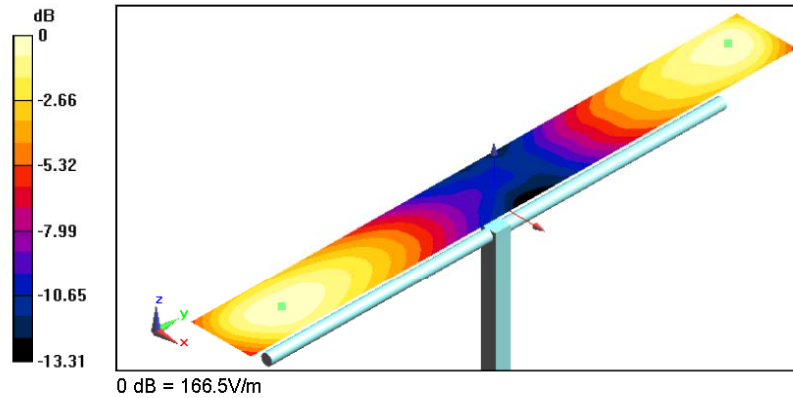
Measurement Standard: DASYS (IEEE/EC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SDHAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (1);

835 MHz / 100mW HAC Dipole Validation at 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm
 Probe Modulation Factor = 1.000
 Device Reference Point: 0, 0, -6.3 mm
 Reference Value = 109.1 V/m; Power Drift = -0.09 dB
 Average value of Peak (interpolated) = 164.9 V/m



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 30 of 88	



PCTEST Hearing-Aid Compatibility Facility

DUT: CD835V3 - SN1003

Type: CD835V3
Serial: 1003

Communication System: CW; Frequency: 835 MHz;

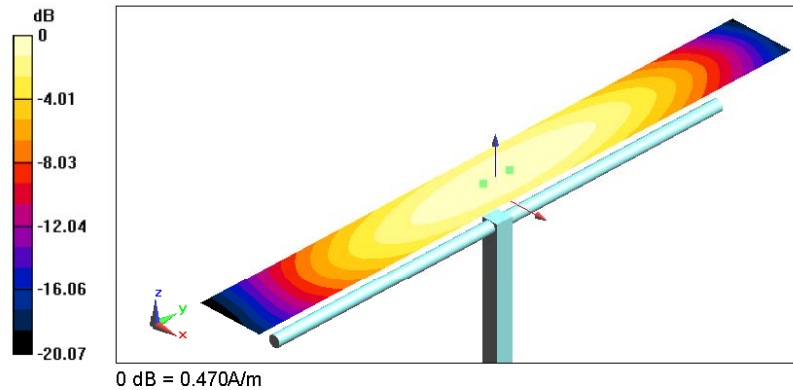
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (1);

835 MHz / 100 mW HAC Validation at 10 mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm
 Probe Modulation Factor = 1.000
 Device Reference Point: 0, 0, -6.3 mm
 Reference Value = 0.502 A/m; Power Drift = -0.16 dB
 Maximum value of Total (interpolated) = 0.472 A/m



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 31 of 88



PCTEST Hearing-Aid Compatibility Facility

DUT: CD1880V3 - SN1137

Type: CD1880V3
Serial: 1137

Communication System: CW; Frequency: 1880 MHz;

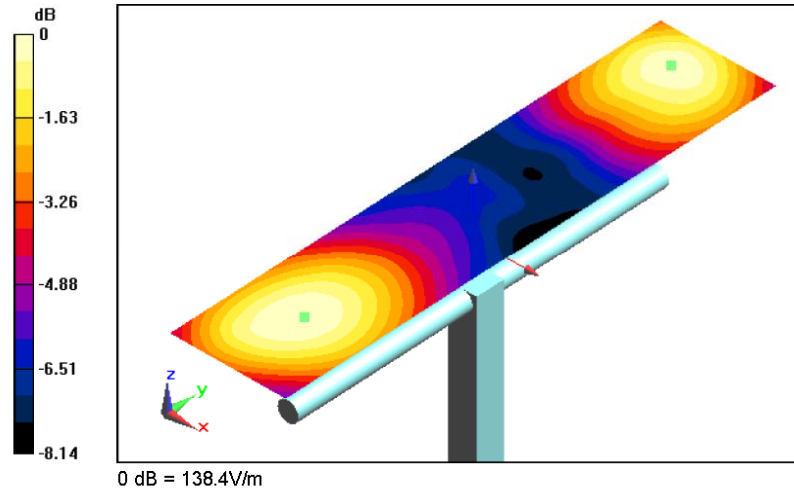
Measurement Standard: DASYS (IEEE/EC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SDHAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (1);

1880 MHz / 100mW HAC Dipole Validation at 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm
 Probe Modulation Factor = 1.000
 Device Reference Point: 0, 0, -6.3 mm
 Reference Value = 155.5 V/m; Power Drift = -0.05 dB
 Average value of Peak (interpolated) = 138.1 V/m



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 32 of 88



PCTEST Hearing-Aid Compatibility Facility

DUT: CD1880V3 - SN1137

Type: CD1880V3
Serial: 1137

Communication System: CW; Frequency: 1880 MHz;

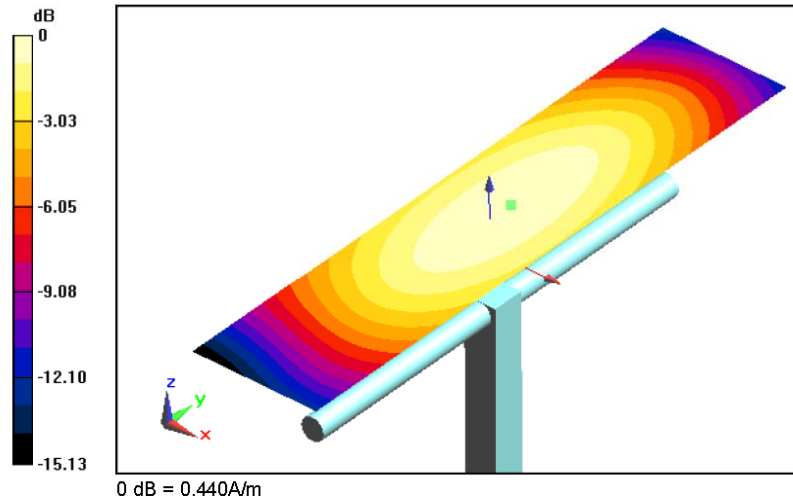
Measurement Standard: DASYS (IEEE/EC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SDHAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (1);

1880 MHz / 100 mW HAC Validation at 10 mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm
 Probe Modulation Factor = 1.000
 Device Reference Point: 0, 0, -6.3 mm
 Reference Value = 0.464 A/m; Power Drift = -0.06 dB
 Maximum value of Total (interpolated) = 0.439 A/m



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 33 of 88



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSCHI415

Type: Portable Handset
 Serial: FCC#3
 Backlight off
 Duty Cycle: 1:8

Communication System: Cell. CDMA; Frequency: 824.7 MHz;

Measurement Standard: DASYS (High Precision Assessment)

DASY5 Configuration:

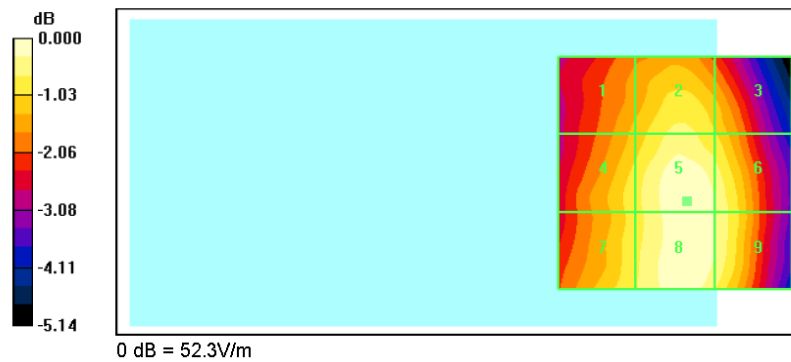
- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

Cell. CDMA, SO3/RC1, Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 52.3 V/m
 Probe Modulation Factor = 3.025
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 21.4 V/m; Power Drift = -0.027 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
45.3 M4	48.9 M4	46.7 M4
Grid 4	Grid 5	Grid 6
47.9 M4	52.3 M4	50.4 M4
Grid 7	Grid 8	Grid 9
48.2 M4	52.1 M4	50.5 M4



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 34 of 88	



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSCHI415

Type: Portable Handset
 Serial: FCC#3
 Backlight off
 Duty Cycle: 1:8

Communication System: Cell. CDMA; Frequency: 836.52 MHz;

Measurement Standard: DASYS (High Precision Assessment)

DASY5 Configuration:

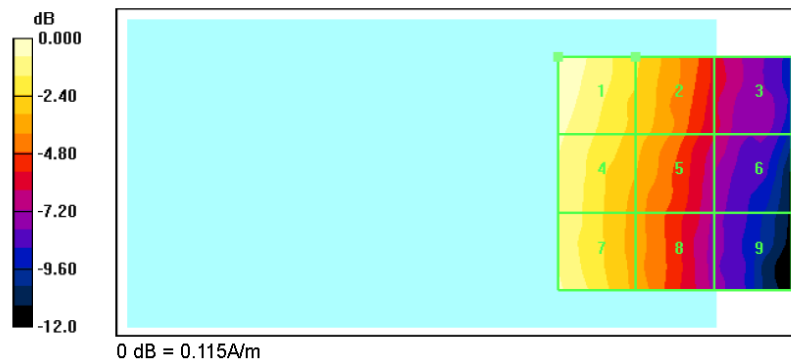
- Probe: HBDV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

Cell. CDMA, SO3/RC1, Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 0.115 A/m
 Probe Modulation Factor = 2.895
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 0.023 A/m; Power Drift = 0.087 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.115 M4	0.089 M4	0.059 M4
Grid 4	Grid 5	Grid 6
0.108 M4	0.084 M4	0.056 M4
Grid 7	Grid 8	Grid 9
0.107 M4	0.078 M4	0.049 M4



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 35 of 88



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSCHI415

Type: Portable Handset
 Serial: FCC#3
 Backlight off
 Duty Cycle: 1:8

Communication System: PCS CDMA; Frequency: 1880 MHz;

Measurement Standard: DASYS (High Precision Assessment)

DASY5 Configuration:

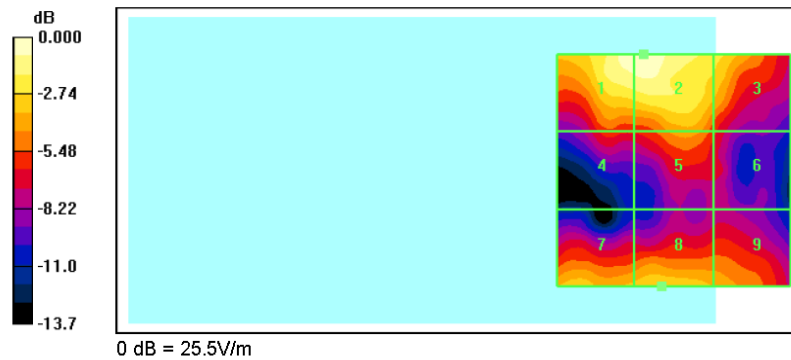
- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

PCS CDMA, SO3/RC1, Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 25.5 V/m
 Probe Modulation Factor = 3.151
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 4.06 V/m; Power Drift = -0.115 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
25.1 M4	25.5 M4	19.8 M4
Grid 4	Grid 5	Grid 6
13.3 M4	16.2 M4	12.8 M4
Grid 7	Grid 8	Grid 9
18.6 M4	18.8 M4	16.7 M4



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 36 of 88



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSCHI415

Type: Portable Handset
 Serial: FCC#3
 Backlight off
 Duty Cycle: 1:8

Communication System: PCS CDMA; Frequency: 1851.25 MHz;

Measurement Standard: DASYS (High Precision Assessment)

DASY5 Configuration:

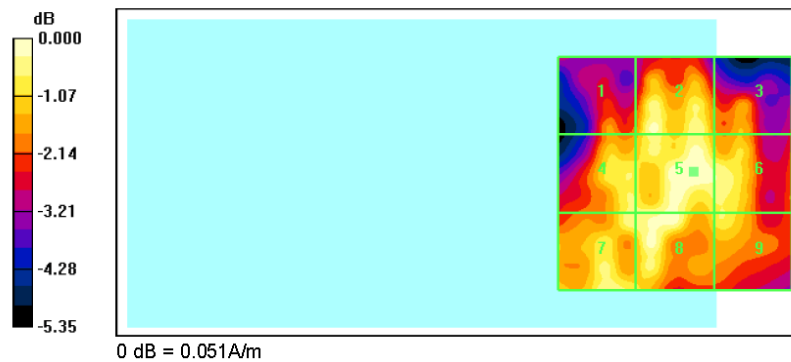
- Probe: HBDV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, V52.8 Build 1;

PCS CDMA, SO3/RC1, Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 0.051 A/m
 Probe Modulation Factor = 2.853
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 0.020 A/m; Power Drift = -0.113 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.042 M4	0.050 M4	0.043 M4
Grid 4	Grid 5	Grid 6
0.048 M4	0.051 M4	0.049 M4
Grid 7	Grid 8	Grid 9
0.049 M4	0.050 M4	0.047 M4



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 37 of 88	



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSCHI415

Type: Portable Handset
 Serial: FCC#3
 Backlight off
 Duty Cycle: 1:1

Communication System: Cell. CDMA; Frequency: 824.7 MHz;

Measurement Standard: DASYS (High Precision Assessment)

DASY5 Configuration:

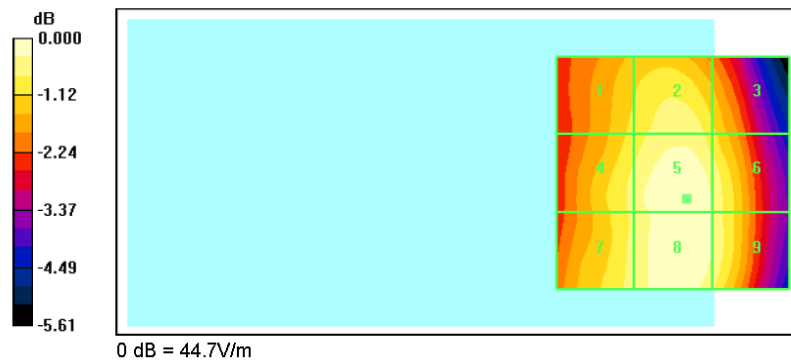
- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

Cell. CDMA, SO55/RC1, Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 44.7 V/m
 Probe Modulation Factor = 0.928
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 61.4 V/m; Power Drift = -0.106 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
39.9 M4	42.3 M4	39.8 M4
Grid 4	Grid 5	Grid 6
41.7 M4	44.7 M4	42.6 M4
Grid 7	Grid 8	Grid 9
41.7 M4	44.6 M4	42.8 M4



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 38 of 88	



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSCHI415

Type: Portable Handset
 Serial: FCC#3
 Backlight off
 Duty Cycle: 1:1

Communication System: Cell. CDMA; Frequency: 836.52 MHz;

Measurement Standard: DASYS (High Precision Assessment)

DASY5 Configuration:

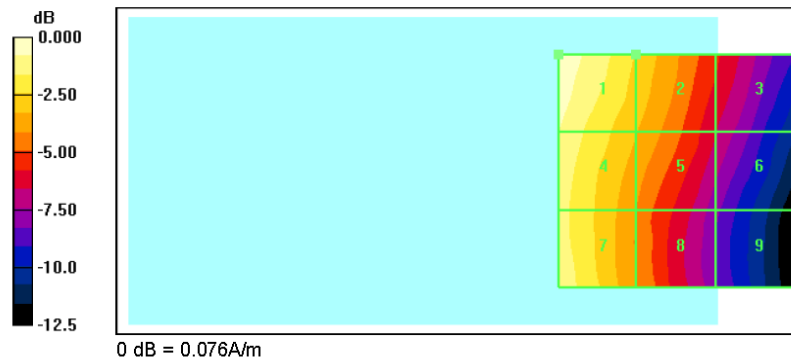
- Probe: HBDV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

Cell. CDMA, SO55/RC1, Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 0.076 A/m
 Probe Modulation Factor = 0.808
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 0.053 A/m; Power Drift = -0.132 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.076 M4	0.057 M4	0.040 M4
Grid 4	Grid 5	Grid 6
0.069 M4	0.052 M4	0.036 M4
Grid 7	Grid 8	Grid 9
0.067 M4	0.047 M4	0.030 M4



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 39 of 88	



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSCHI415

Type: Portable Handset
 Serial: FCC#3
 Backlight off
 Duty Cycle: 1:1

Communication System: PCS CDMA; Frequency: 1851.25 MHz;

Measurement Standard: DASYS (High Precision Assessment)

DASY5 Configuration:

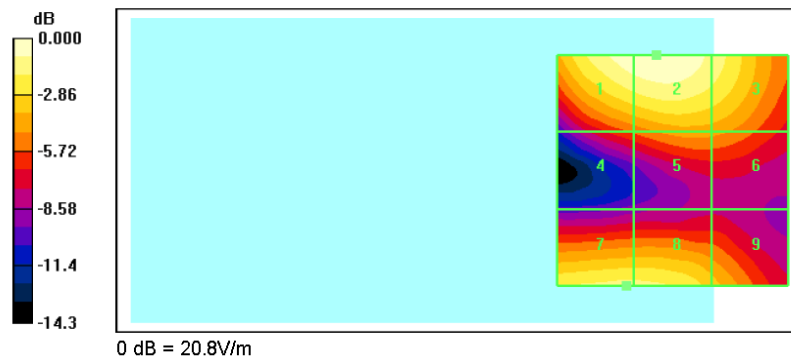
- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

PCS CDMA, SO55/RC1, Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 20.8 V/m
 Probe Modulation Factor = 0.990
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 8.52 V/m; Power Drift = -0.046 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
20.2 M4	20.8 M4	18.1 M4
Grid 4	Grid 5	Grid 6
11.1 M4	12.8 M4	12.6 M4
Grid 7	Grid 8	Grid 9
17.6 M4	17.5 M4	14.2 M4



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 40 of 88



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSCHI415

Type: Portable Handset
 Serial: FCC#3
 Backlight off
 Duty Cycle: 1:1

Communication System: PCS CDMA; Frequency: 1880 MHz;

Measurement Standard: DASYS (High Precision Assessment)

DASY5 Configuration:

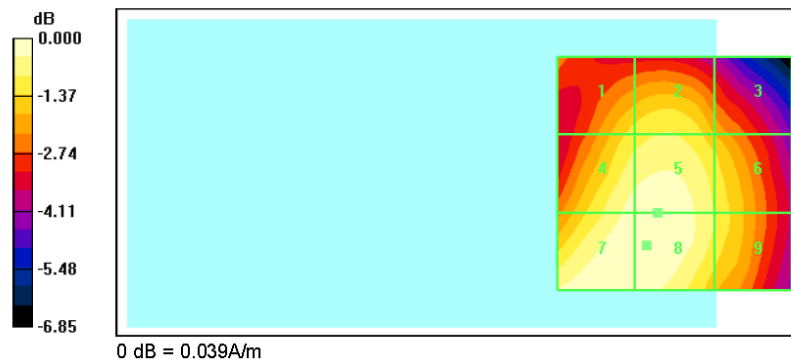
- Probe: HBDV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

PCS CDMA, SO55/RC1, Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 0.039 A/m
 Probe Modulation Factor = 0.820
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 0.052 A/m; Power Drift = 0.067 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.034 M4	0.035 M4	0.032 M4
Grid 4	Grid 5	Grid 6
0.038 M4	0.038 M4	0.035 M4
Grid 7	Grid 8	Grid 9
0.039 M4	0.039 M4	0.035 M4



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 41 of 88



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSCHI415

Type: Portable Handset
 Serial: FCC#3
 Backlight off
 Duty Cycle: 1:8.3

Communication System: GSM850; Frequency: 848.8 MHz;

Measurement Standard: DASYS (High Precision Assessment)

DASY5 Configuration:

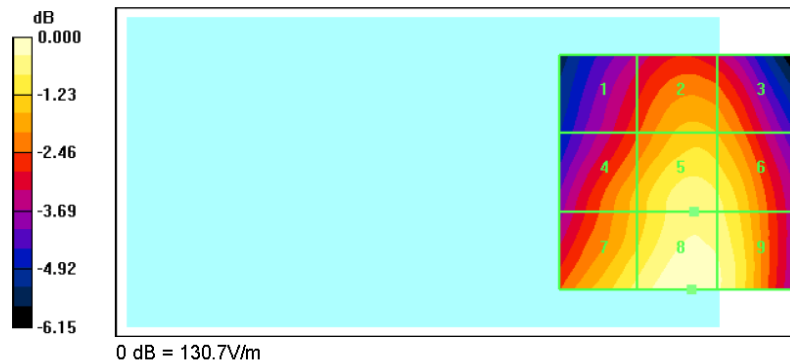
- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, v52.8 Build 1;

GSM850 High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 130.7 V/m
 Probe Modulation Factor = 2.829
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 52.0 V/m; Power Drift = 0.024 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
97.8 M4	110.4 M4	108.0 M4
Grid 4	Grid 5	Grid 6
110.7 M4	123.3 M4	121.0 M4
Grid 7	Grid 8	Grid 9
121.1 M4	130.7 M4	126.2 M4



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 42 of 88



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSCHI415

Type: Portable Handset
 Serial: FCC#3
 Backlight off
 Duty Cycle: 1:8.3

Communication System: GSM850; Frequency: 836.6 MHz;

Measurement Standard: DASYS (High Precision Assessment)

DASY5 Configuration:

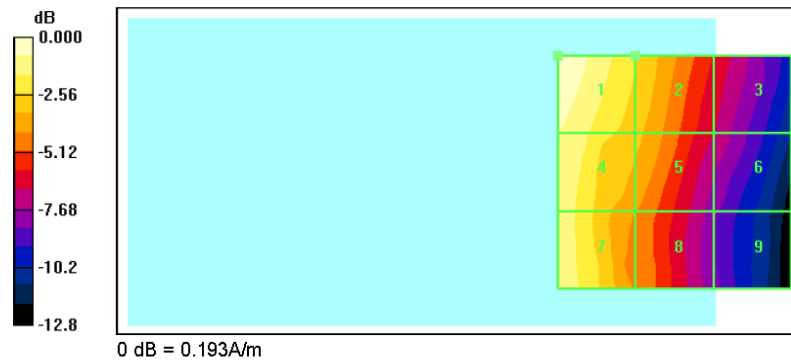
- Probe: HBDV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

GSM850 Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 0.193 A/m
 Probe Modulation Factor = 1.948
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 0.055 A/m; Power Drift = -0.162 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.193 M4	0.146 M4	0.096 M4
Grid 4	Grid 5	Grid 6
0.176 M4	0.135 M4	0.088 M4
Grid 7	Grid 8	Grid 9
0.170 M4	0.119 M4	0.075 M4



2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 43 of 88	



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSCHI415

Type: Portable Handset

Serial: FCC#3

*Backlight off**Duty Cycle: 1:8.3*

Communication System: GSM1900; Frequency: 1880 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

GSM1900 Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 52.1 V/m

Probe Modulation Factor = 2.79

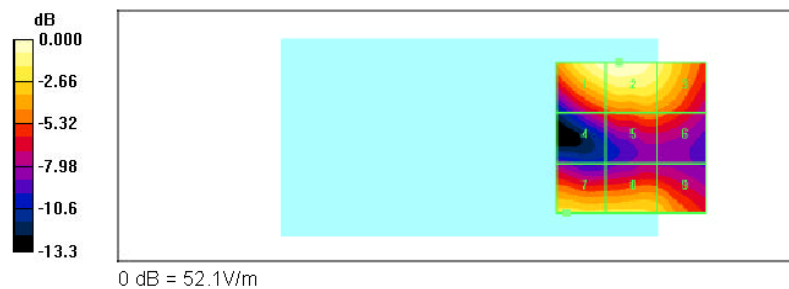
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 8.64 V/m; Power Drift = 0.102 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
50.4 M3	52.1 M3	45.5 M4
Grid 4	Grid 5	Grid 6
26.9 M4	31.3 M4	30.6 M4
Grid 7	Grid 8	Grid 9
41.1 M4	40.3 M4	37.9 M4



PCTEST 2012

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 44 of 88



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSCHI415

Type: Portable Handset
 Serial: FCC#3
 Backlight off
 Duty Cycle: 1:8.3

Communication System: GSM1900; Frequency: 1850.2 MHz;

Measurement Standard: DASYS (High Precision Assessment)

DASY5 Configuration:

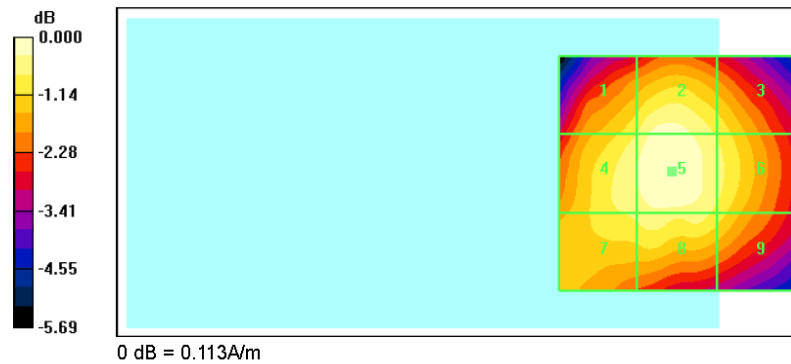
- Probe: HBDV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn649; Calibrated: 2/20/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

GSM1900 Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 0.113 A/m
 Probe Modulation Factor = 2.319
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 0.057 A/m; Power Drift = 0.017 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.104 M4	0.110 M4	0.103 M4
Grid 4	Grid 5	Grid 6
0.108 M4	0.113 M4	0.105 M4
Grid 7	Grid 8	Grid 9
0.105 M4	0.107 M4	0.102 M4





2012 PCTEST

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 45 of 88

14. CALIBRATION CERTIFICATES

The following pages include the probe calibration used to evaluate HAC for the DUT.

FCC ID: A3LSCHI415		HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 46 of 88



Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client **PC Test**

Certificate No: **ER3-2353_Jan12**

CALIBRATION CERTIFICATE

Object: **ER3DV6 - SN:2353**

Calibration procedure(s): **QA CAL-02.v6, QA CAL-25.v4
Calibration procedure for E-field probes optimized for close near field evaluations in air**

Calibration date: **January 20, 2012**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

✓
KOK
2/6/2012

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	31-Mar-11 (No. 217-01372)	Apr-12
Power sensor E4412A	MY41498087	31-Mar-11 (No. 217-01372)	Apr-12
Reference 3 dB Attenuator	SN: S5054 (3c)	29-Mar-11 (No. 217-01369)	Apr-12
Reference 20 dB Attenuator	SN: S5086 (20b)	29-Mar-11 (No. 217-01367)	Apr-12
Reference 30 dB Attenuator	SN: S5129 (30b)	29-Mar-11 (No. 217-01370)	Apr-12
Reference Probe ER3DV6	SN: 2328	11-Oct-11 (No. ER3-2328_Oct11)	Oct-12
DAE4	SN: 789	6-Apr-11 (No. DAE4-789_Apr11)	Apr-12
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-11)	In house check: Apr-13
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12

Calibrated by: **Dirce Iliev** (Name), **Laboratory Technician** (Function), *[Signature]* (Signature)

Approved by: **Katja Pokovic** (Name), **Technical Manager** (Function), *[Signature]* (Signature)

Issued: January 25, 2012

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 47 of 88



Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Glossary:

NORM _{x,y,z}	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., $\vartheta = 0$ is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

- a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- *NORM_{x,y,z}*: Assessed for E-field polarization $\vartheta = 0$ for XY sensors and $\vartheta = 90$ for Z sensor ($f \leq 900$ MHz in TEM-cell; $f > 1800$ MHz: R22 waveguide).
- *NORM(f)_{x,y,z}* = *NORM_{x,y,z}* * *frequency_response* (see Frequency Response Chart).
- *DCP_{x,y,z}*: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- *PAR*: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- *A_{x,y,z}*; *B_{x,y,z}*; *C_{x,y,z}*; *VR_{x,y,z}*: A, B, C are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the *NORM_x* (no uncertainty required).



FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 48 of 88

Probe ER3DV6

SN:2353

Manufactured: March 8, 2005
 Calibrated: January 20, 2012

Calibrated for DASY/EASY Systems
 (Note: non-compatible with DASY2 system!)



FCC ID: A3LSCHI415		HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 49 of 88	

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2353**Basic Calibration Parameters**

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm ($\mu\text{V}/(\text{V}/\text{m})^2$)	1.53	1.73	1.81	$\pm 10.1\%$
DCP (mV) ^B	100.9	98.7	102.3	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc ^E (k=2)
10000	CW	0.00	X	0.00	0.00	1.00	103.6	$\pm 3.0\%$
			Y	0.00	0.00	1.00	88.2	
			Z	0.00	0.00	1.00	105.7	
10011	UMTS-FDD (WCDMA)	3.40	X	3.44	65.6	18.3	111.4	$\pm 0.7\%$
			Y	3.51	65.9	18.5	130.9	
			Z	3.53	66.6	18.9	114.5	
10021	GSM-FDD (TDMA, GMSK)	9.40	X	16.75	99.3	28.2	144.6	$\pm 1.7\%$
			Y	16.85	99.3	28.8	124.1	
			Z	22.94	99.8	28.7	128.7	
10039	CDMA2000 (1xRTT, RC1)	4.57	X	4.56	66.0	18.8	112.4	$\pm 0.9\%$
			Y	4.84	67.1	19.5	133.1	
			Z	4.49	65.9	18.7	115.8	
10081	CDMA2000 (1xRTT, RC3)	3.96	X	3.68	64.9	18.0	109.1	$\pm 0.7\%$
			Y	3.89	65.9	18.7	129.0	
			Z	3.71	65.4	18.4	113.2	
10169	LTE-FDD (SC-FDMA, 1 RB, 20 MHz, QPSK)	5.73	X	5.16	67.7	20.5	145.7	$\pm 1.7\%$
			Y	5.14	67.1	20.3	124.7	
			Z	4.82	65.7	19.3	108.5	
10170	LTE-FDD (SC-FDMA, 1 RB, 20 MHz, 16-QAM)	6.52	X	6.10	69.5	21.9	146.2	$\pm 2.7\%$
			Y	6.13	69.1	21.8	125.5	
			Z	5.66	67.0	20.2	110.4	
10175	LTE-FDD (SC-FDMA, 1 RB, 10 MHz, QPSK)	5.73	X	5.13	67.6	20.5	145.7	$\pm 1.7\%$
			Y	5.15	67.1	20.3	124.9	
			Z	4.88	66.0	19.4	110.1	
10176	LTE-FDD (SC-FDMA, 1 RB, 10 MHz, 16-QAM)	6.52	X	6.12	69.6	22.0	145.7	$\pm 3.0\%$
			Y	6.12	69.2	21.9	124.6	
			Z	5.69	67.2	20.4	110.6	
10177	LTE-FDD (SC-FDMA, 1 RB, 5 MHz, QPSK)	5.73	X	5.19	67.8	20.6	145.8	$\pm 1.7\%$
			Y	5.17	67.3	20.4	124.7	
			Z	4.88	66.0	19.4	110.3	
10178	LTE-FDD (SC-FDMA, 1 RB, 5 MHz, 16-QAM)	6.52	X	6.05	69.3	21.8	146.8	$\pm 2.5\%$
			Y	5.98	68.5	21.5	123.9	
			Z	5.55	66.6	20.1	109.9	
10181	LTE-FDD (SC-FDMA, 1 RB, 15 MHz, QPSK)	5.73	X	5.17	67.8	20.6	145.9	$\pm 1.7\%$
			Y	4.92	66.1	19.7	123.5	
			Z	4.90	66.1	19.5	110.0	



FCC ID: A3LSCHI415		HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 50 of 88

10182	LTE-FDD (SC-FDMA, 1 RB, 15 MHz, 16-QAM)	6.52	X	6.00	69.1	21.7	146.3	±3.0 %
			Y	6.43	70.5	22.6	125.7	
			Z	5.70	67.2	20.4	110.4	

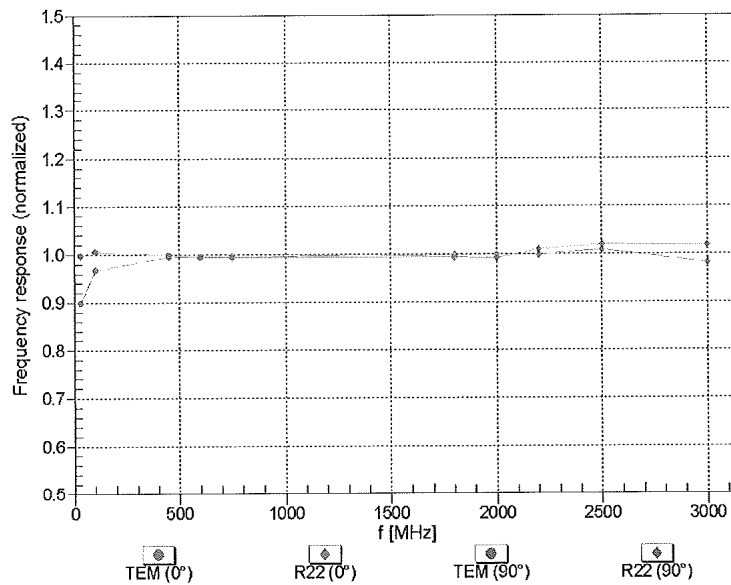
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor $k=2$, which for a normal distribution corresponds to a coverage probability of approximately 95%.

^B Numerical linearization parameter: uncertainty not required.



^E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 51 of 88

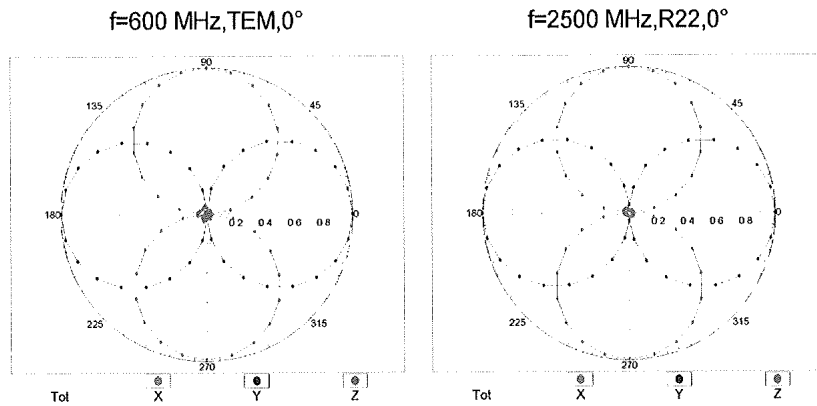
Frequency Response of E-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)



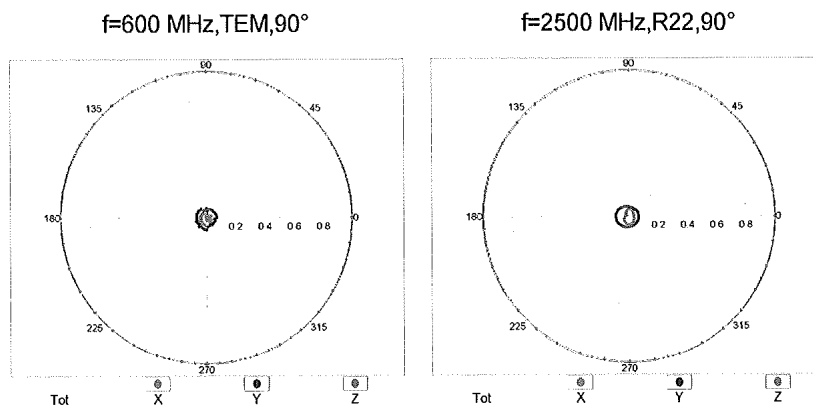
Uncertainty of Frequency Response of E-field: $\pm 6.3\%$ (k=2)



FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 52 of 88

Receiving Pattern (ϕ), $\vartheta = 0^\circ$

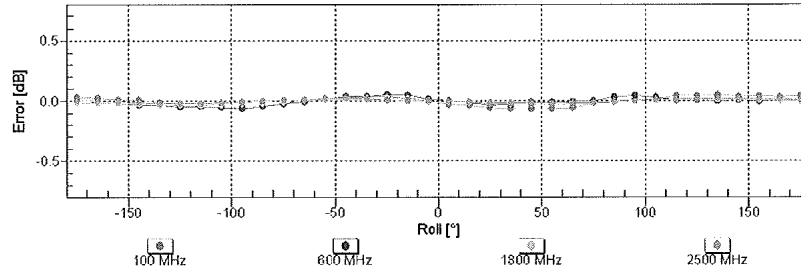


Receiving Pattern (ϕ), $\vartheta = 90^\circ$



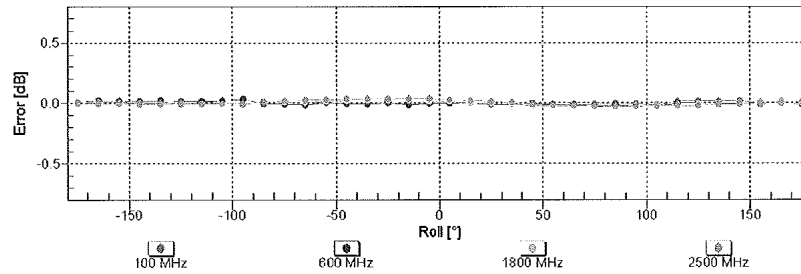
FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 53 of 88

Receiving Pattern (ϕ), $\vartheta = 0^\circ$





Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

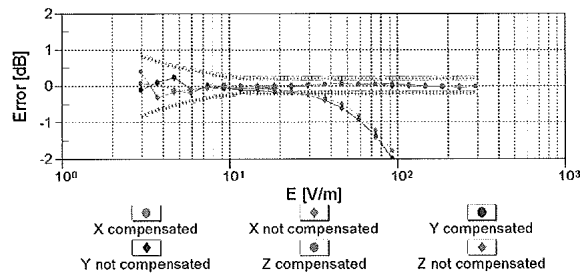
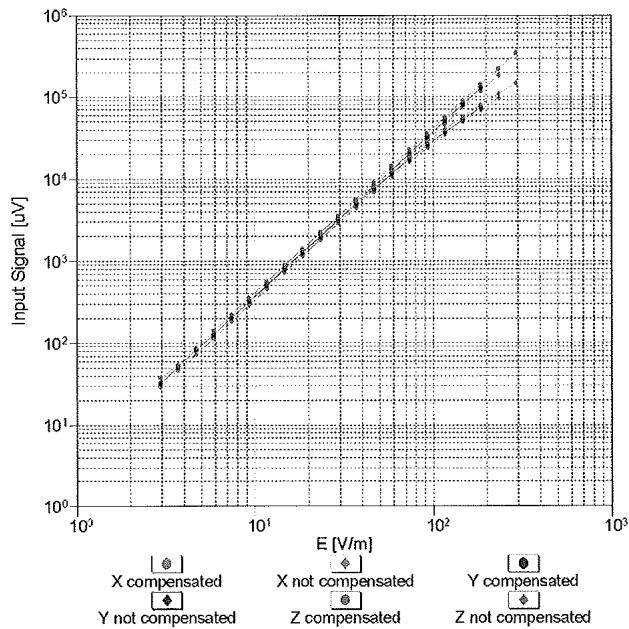
Receiving Pattern (ϕ), $\vartheta = 90^\circ$



Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

<p>FCC ID: A3LSCHI415</p>		<p>HAC (RF EMISSIONS) TEST REPORT</p> 	<p>Reviewed by: Quality Manager</p>
<p>HAC Filename: OY1205290740.A3L</p>	<p>Test Dates: June 19-25, 2012</p>	<p>EUT Type: Portable Handset</p>	<p>Page 54 of 88</p>

Dynamic Range f(E-field) (TEM cell , f = 900 MHz)

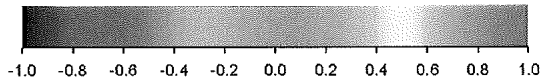
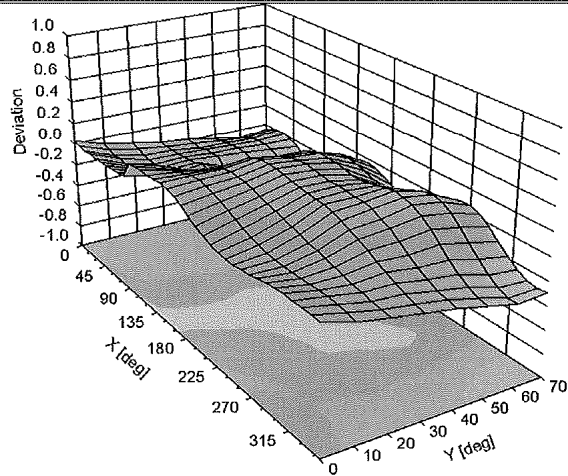


Uncertainty of Linearity Assessment: ± 0.6% (k=2)



FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 55 of 88

Deviation from Isotropy in Air

Error (ϕ, θ), $f = 900$ MHz





Uncertainty of Spherical Isotropy Assessment: $\pm 2.6\%$ ($k=2$)

FCC ID: A3LSCHI415		HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 56 of 88	

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2353**Other Probe Parameters**

Sensor Arrangement	Rectangular
Connector Angle (°)	-4.9
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 57 of 88	



Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client **PC Test**

Certificate No: **H3-6207_Jan12**

CALIBRATION CERTIFICATE

Object: **H3DV6 - SN:6207**

Calibration procedure(s): **QA CAL-03.v6, QA CAL-25.v4
Calibration procedure for H-field probes optimized for close near field evaluations in air**

Calibration date: **January 20, 2012** ✓ KOK 2/6/12

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	31-Mar-11 (No. 217-01372)	Apr-12
Power sensor E4412A	MY41498087	31-Mar-11 (No. 217-01372)	Apr-12
Reference 3 dB Attenuator	SN: S5054 (3c)	29-Mar-11 (No. 217-01369)	Apr-12
Reference 20 dB Attenuator	SN: S5086 (20b)	29-Mar-11 (No. 217-01367)	Apr-12
Reference 30 dB Attenuator	SN: S5129 (30b)	29-Mar-11 (No. 217-01370)	Apr-12
Reference Probe H3DV6	SN: 6182	11-Oct-11 (No. H3-6182_Oct11)	Oct-12
DAE4	SN: 789	6-Apr-11 (No. DAE4-789_Apr11)	Apr-12
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-11)	In house check: Apr-13
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12

Calibrated by: **Dimce Iliev** (Name), **Laboratory Technician** (Function), *[Signature]* (Signature)

Approved by: **Katja Pokovic** (Name), **Technical Manager** (Function), *[Signature]* (Signature)

Issued: January 25, 2012

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 58 of 88



Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Glossary:

NORM_{x,y,z} sensitivity in free space
DCP diode compression point
CF crest factor (1/duty_cycle) of the RF signal
A, B, C modulation dependent linearization parameters
Polarization φ φ rotation around probe axis
Polarization ϑ ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center),
i.e., $\vartheta = 0$ is normal to probe axis
Connector Angle information used in DASYS system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

- a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- NORM_{x,y,z}: Assessed for E-field polarization $\vartheta = 0$ for XY sensors and $\vartheta = 90$ for Z sensor ($f \leq 900$ MHz in TEM-cell; $f > 1800$ MHz: R22 waveguide).
- X,Y,Z(f)_a0a1a2= X,Y,Z_a0a1a2* frequency_response (see Frequency Response Chart).
- DCP_{x,y,z}: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z, VRx,y,z: A, B, C are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the X_a0a1a2 (no uncertainty required).



FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 59 of 88

Probe H3DV6

SN:6207

Manufactured: June 12, 2006
 Calibrated: January 20, 2012

Calibrated for DASY/EASY Systems
 (Note: non-compatible with DASY2 system!)

FCC ID: A3LSCHI415		HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 60 of 88	

DASY/EASY - Parameters of Probe: H3DV6 - SN:6207**Basic Calibration Parameters**

		Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (A/m / $\sqrt{\text{mV}}$)	a0	2.41E-003	2.37E-003	2.94E-003	$\pm 5.1 \%$
Norm (A/m / $\sqrt{\text{mV}}$)	a1	1.77E-004	6.07E-004	8.69E-005	$\pm 5.1 \%$
Norm (A/m / $\sqrt{\text{mV}}$)	a2	1.63E-004	2.45E-004	1.96E-004	$\pm 5.1 \%$
DCP (mV) ^B		94.0	94.6	94.5	



Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc ^E (k=2)
10000	CW	0.00	X	0.00	0.00	1.00	92.5	$\pm 2.7 \%$
			Y	0.00	0.00	1.00	107.4	
			Z	0.00	0.00	1.00	119.1	

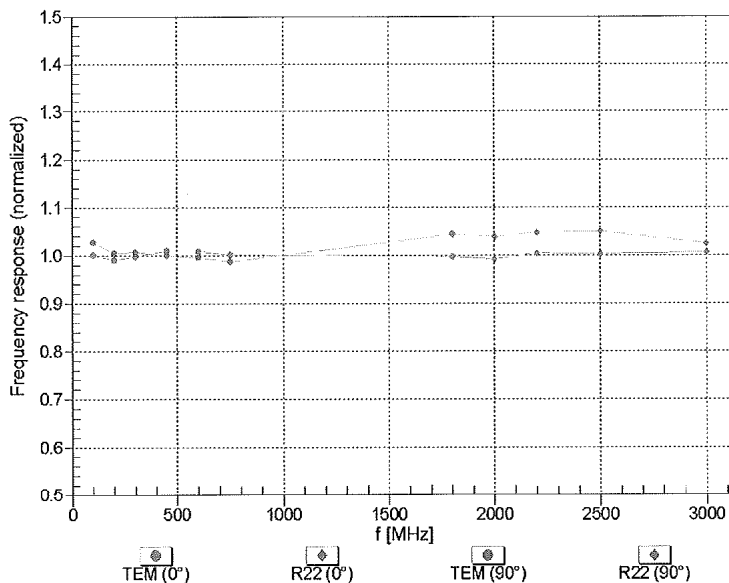
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

^B Numerical linearization parameter; uncertainty not required.

^E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

FCC ID: A3LSCHI415		HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 61 of 88

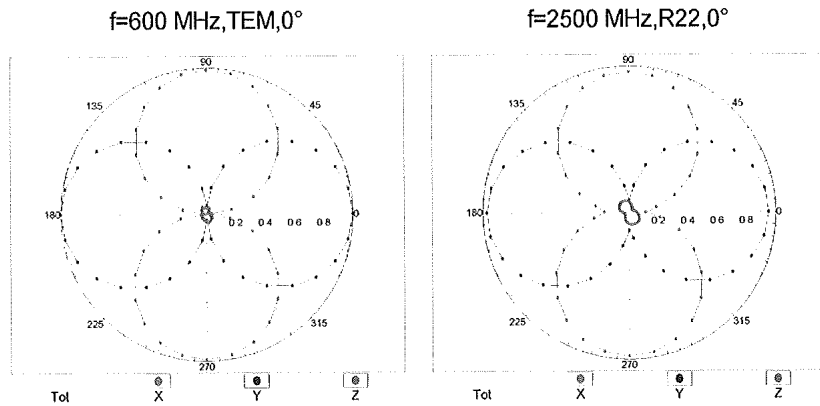
Frequency Response of H-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)



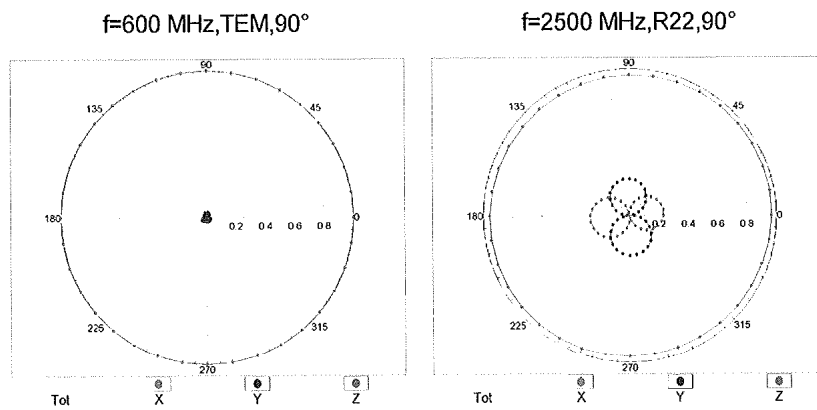
Uncertainty of Frequency Response of H-field: ± 6.3% (k=2)



FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 62 of 88

Receiving Pattern (ϕ), $\vartheta = 0^\circ$

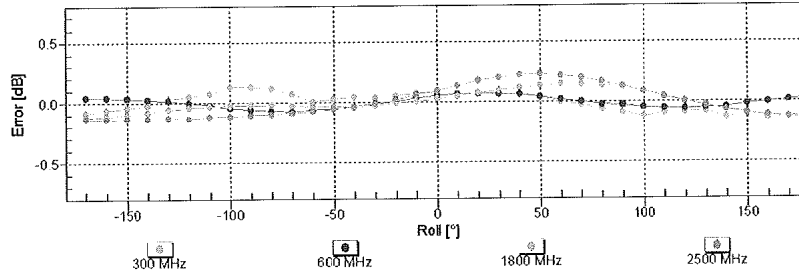


Receiving Pattern (ϕ), $\vartheta = 90^\circ$



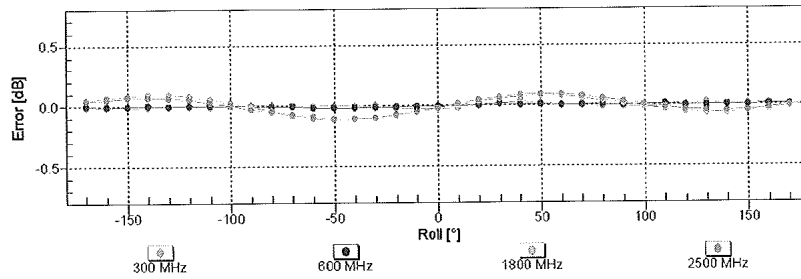
FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 63 of 88

Receiving Pattern (ϕ), $\vartheta = 0^\circ$





Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

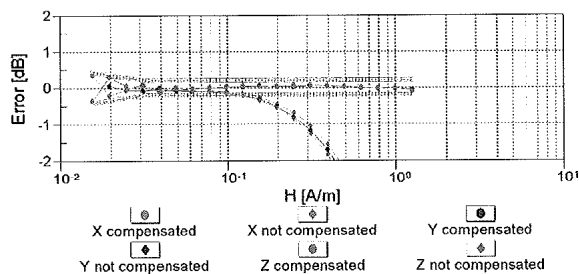
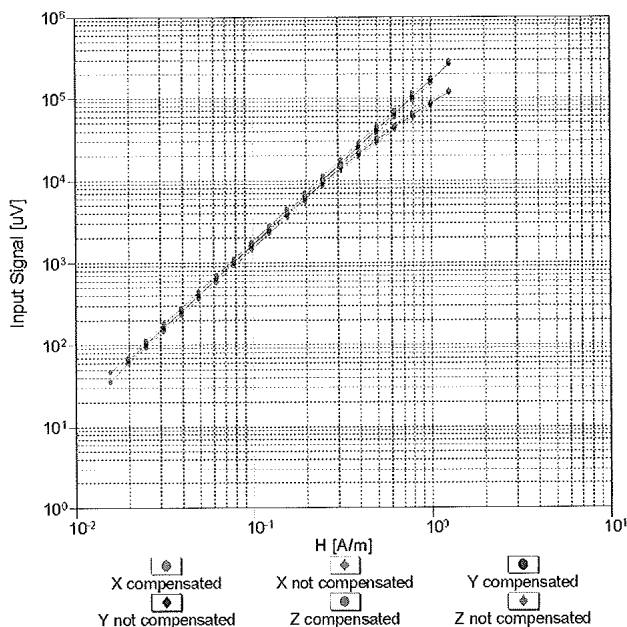
Receiving Pattern (ϕ), $\vartheta = 90^\circ$



Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

<p>FCC ID: A3LSCHI415</p>		<p>HAC (RF EMISSIONS) TEST REPORT</p> 	<p>Reviewed by: Quality Manager</p>
<p>HAC Filename: OY1205290740.A3L</p>	<p>Test Dates: June 19-25, 2012</p>	<p>EUT Type: Portable Handset</p>	<p>Page 64 of 88</p>

Dynamic Range f(H-field) (TEM cell, f = 900 MHz)

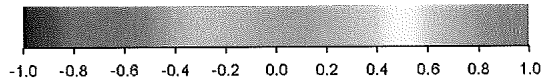
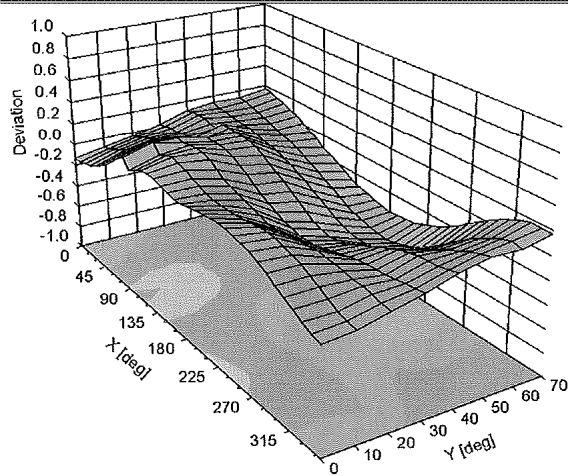


Uncertainty of Linearity Assessment: ± 0.6% (k=2)



FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 65 of 88

Deviation from Isotropy in Air

Error (ϕ, θ), $f = 900$ MHz





Uncertainty of Spherical Isotropy Assessment: $\pm 2.6\%$ ($k=2$)

FCC ID: A3LSCHI415	 <small>ENGINEERING LABORATORY, INC.</small>	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 66 of 88	

DASY/EASY - Parameters of Probe: H3DV6 - SN:6207

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	179.8
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	20 mm
Tip Diameter	6 mm
Probe Tip to Sensor X Calibration Point	3 mm
Probe Tip to Sensor Y Calibration Point	3 mm
Probe Tip to Sensor Z Calibration Point	3 mm

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 67 of 88

**Calibration Laboratory of
Schmid & Partner
Engineering AG**
Zeughausstrasse 43, 8004 Zurich, Switzerland



S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **PC Test**

Certificate No: **CD835V3-1003_Feb11**

CALIBRATION CERTIFICATE																																																			
Object	CD835V3 - SN: 1003																																																		
Calibration procedure(s)	QA CAL-20.v5 Calibration procedure for dipoles in air																																																		
Calibration date:	February 08, 2011																																																		
<p>This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.</p> <p>Calibration Equipment used (M&TE critical for calibration)</p> <table border="1"> <thead> <tr> <th>Primary Standards</th> <th>ID #</th> <th>Cal Date (Certificate No.)</th> <th>Scheduled Calibration</th> </tr> </thead> <tbody> <tr> <td>Power meter EPM-442A</td> <td>GB37480704</td> <td>06-Oct-10 (No. 217-01266)</td> <td>Oct-11</td> </tr> <tr> <td>Power sensor HP 8481A</td> <td>US37292783</td> <td>06-Oct-10 (No. 217-01266)</td> <td>Oct-11</td> </tr> <tr> <td>Probe ER3DV6</td> <td>SN: 2336</td> <td>29-Dec-10 (No. ER3-2336_Dec10)</td> <td>Dec-11</td> </tr> <tr> <td>Probe H3DV6</td> <td>SN: 6065</td> <td>29-Dec-10 (No. H3-6065_Dec10)</td> <td>Dec-11</td> </tr> <tr> <td>DAE4</td> <td>SN: 781</td> <td>20-Oct-10 (No. DAE4-781_Oct10)</td> <td>Oct-11</td> </tr> </tbody> </table> <table border="1"> <thead> <tr> <th>Secondary Standards</th> <th>ID #</th> <th>Check Date (in house)</th> <th>Scheduled Check</th> </tr> </thead> <tbody> <tr> <td>Power meter Agilent 4419B</td> <td>SN: GB42420191</td> <td>09-Oct-09 (in house check Oct-10)</td> <td>In house check: Oct-11</td> </tr> <tr> <td>Power sensor HP 8482H</td> <td>SN: 3318A09450</td> <td>09-Oct-09 (in house check Oct-10)</td> <td>In house check: Oct-11</td> </tr> <tr> <td>Power sensor HP 8482A</td> <td>SN: US37295597</td> <td>09-Oct-09 (in house check Oct-10)</td> <td>In house check: Oct-11</td> </tr> <tr> <td>Network Analyzer HP 8753E</td> <td>US37390585</td> <td>18-Oct-01 (in house check Oct-10)</td> <td>In house check: Oct-11</td> </tr> <tr> <td>RF generator E4433B</td> <td>MY 41000675</td> <td>03-Nov-04 (in house check Oct-09)</td> <td>In house check: Oct-11</td> </tr> </tbody> </table>				Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration	Power meter EPM-442A	GB37480704	06-Oct-10 (No. 217-01266)	Oct-11	Power sensor HP 8481A	US37292783	06-Oct-10 (No. 217-01266)	Oct-11	Probe ER3DV6	SN: 2336	29-Dec-10 (No. ER3-2336_Dec10)	Dec-11	Probe H3DV6	SN: 6065	29-Dec-10 (No. H3-6065_Dec10)	Dec-11	DAE4	SN: 781	20-Oct-10 (No. DAE4-781_Oct10)	Oct-11	Secondary Standards	ID #	Check Date (in house)	Scheduled Check	Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-10)	In house check: Oct-11	Power sensor HP 8482H	SN: 3318A09450	09-Oct-09 (in house check Oct-10)	In house check: Oct-11	Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-10)	In house check: Oct-11	Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-10)	In house check: Oct-11	RF generator E4433B	MY 41000675	03-Nov-04 (in house check Oct-09)	In house check: Oct-11
Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration																																																
Power meter EPM-442A	GB37480704	06-Oct-10 (No. 217-01266)	Oct-11																																																
Power sensor HP 8481A	US37292783	06-Oct-10 (No. 217-01266)	Oct-11																																																
Probe ER3DV6	SN: 2336	29-Dec-10 (No. ER3-2336_Dec10)	Dec-11																																																
Probe H3DV6	SN: 6065	29-Dec-10 (No. H3-6065_Dec10)	Dec-11																																																
DAE4	SN: 781	20-Oct-10 (No. DAE4-781_Oct10)	Oct-11																																																
Secondary Standards	ID #	Check Date (in house)	Scheduled Check																																																
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-10)	In house check: Oct-11																																																
Power sensor HP 8482H	SN: 3318A09450	09-Oct-09 (in house check Oct-10)	In house check: Oct-11																																																
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-10)	In house check: Oct-11																																																
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-10)	In house check: Oct-11																																																
RF generator E4433B	MY 41000675	03-Nov-04 (in house check Oct-09)	In house check: Oct-11																																																
Calibrated by:	Name Claudio Leubler	Function Laboratory Technician	Signature 																																																
Approved by:	Name Katja Pokovic	Technical Manager																																																	
Issued: February 10, 2011																																																			
This calibration certificate shall not be reproduced except in full without written approval of the laboratory.																																																			

✓
KOK
2/12/11

Certificate No: CD835V3-1003_Feb11

Page 1 of 6

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 68 of 88



Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

References

- [1] ANSI-C63.19-2006
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.
- [2] ANSI-C63.19-2007
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- *Coordinate System:* y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1, 2], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm above the top edge of the dipole arms.
- *Measurement Conditions:* Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- *Antenna Positioning:* The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- *Feed Point Impedance and Return Loss:* These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminated by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- *E- field distribution:* E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1, 2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- *H-field distribution:* H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 69 of 88

1 Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.6.1 (408)
DASY PP Version	SEMCAD X	V14.4.2 (2595)
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 180 mm
Frequency	835 MHz ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

2 Maximum Field values

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW forward power	0.458 A/m

Uncertainty for H-field measurement: 8.2% (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end-	100 mW forward power	170.7 V/m
Maximum measured above low end	100 mW forward power	161.3 V/m
Averaged maximum above arm	100 mW forward power	166.0 V/m

Uncertainty for E-field measurement: 12.8% (k=2)

3 Appendix

3.1 Antenna Parameters

Frequency	Return Loss	Impedance
800 MHz	16.6 dB	(41.9 – j11.1) Ohm
835 MHz	24.1 dB	(48.2 + j5.9) Ohm
900 MHz	16.5 dB	(58.5 – j14.0) Ohm
950 MHz	17.9 dB	(49.3 + j12.8) Ohm
960 MHz	12.9 dB	(62.2 + j22.8) Ohm



3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

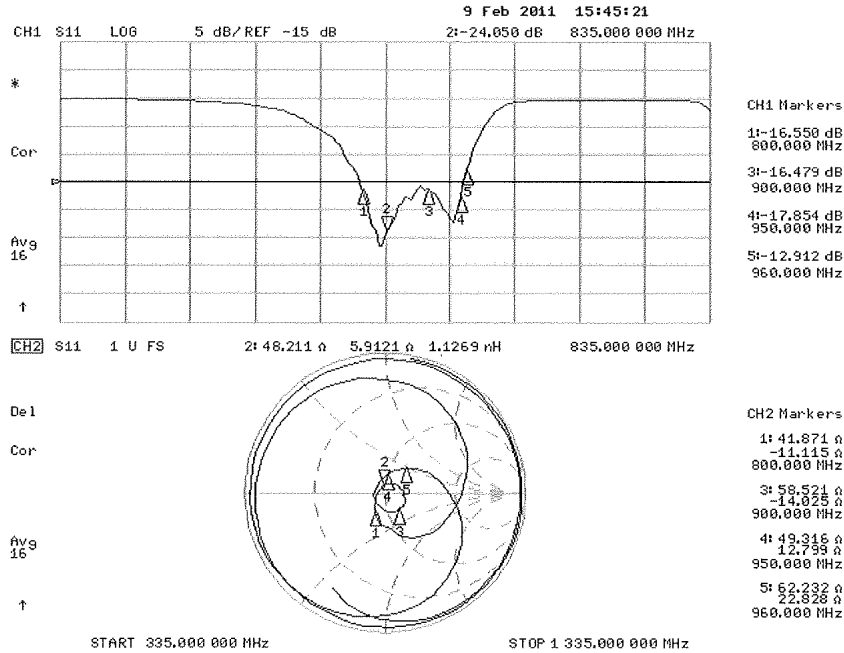
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 70 of 88

3.3 Measurement Sheets

3.3.1 Return Loss and Smith Chart



FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 71 of 88

3.3.3 DASY4 H-field Result

Date/Time: 08.02.2011 13:00:11

Test Laboratory: SPEAG Lab2

HAC RF_CD835_1003_H_110208_CL

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: 1003

Communication System: CW; Frequency: 835 MHz
 Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
 Phantom section: RF Section
 Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole H-Field measurement @ 835MHz/H Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.458 A/m

Probe Modulation Factor = 1.000

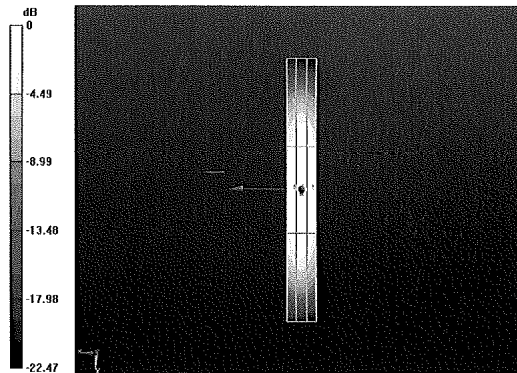
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.488 A/m; Power Drift = -0.0088 dB



Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.376 M4	Grid 2 0.398 M4	Grid 3 0.379 M4
Grid 4 0.435 M4	Grid 5 0.458 M4	Grid 6 0.434 M4
Grid 7 0.388 M4	Grid 8 0.407 M4	Grid 9 0.381 M4



0 dB = 0.460A/m

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 72 of 88

3.3.2 DASY4 E-field Result

Date/Time: 08.02.2011 13:58:56

Test Laboratory: SPEAG Lab2

HAC RF_CD835_1003_E_110208_CL

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: 1003

Communication System: CW; Frequency: 835 MHz

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole E-Field measurement @ 835MHz/E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 170.7 V/m

Probe Modulation Factor = 1.000

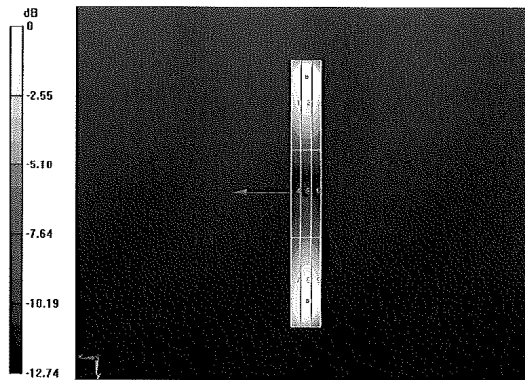
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 123.4 V/m; Power Drift = 0.02 dB



Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 164.3 M4	Grid 2 170.7 M4	Grid 3 164.5 M4
Grid 4 85.8 M4	Grid 5 90.5 M4	Grid 6 88.8 M4
Grid 7 152.9 M4	Grid 8 161.3 M4	Grid 9 158.3 M4



0 dB = 170.7V/m

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 73 of 88

**Calibration Laboratory of
Schmid & Partner
Engineering AG**
Zeughausstrasse 43, 8004 Zurich, Switzerland



S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **PC Test**

Certificate No: **CD1880V3-1137_Feb11/2**

CALIBRATION CERTIFICATE (Replacement of No: CD1880V3-1137_Feb11)

Object: **CD1880V3 - SN: 1137**

Calibration procedure(s): **QA CAL-20.v5
Calibration procedure for dipoles in air**

Calibration date: **February 09, 2011**

*✓
Kok
21/2/11*

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	06-Oct-10 (No. 217-01266)	Oct-11
Power sensor HP 8481A	US37292783	06-Oct-10 (No. 217-01266)	Oct-11
Probe ER3DV6	SN: 2336	29-Dec-10 (No. ER3-2336_Dec10)	Dec-11
Probe H3DV6	SN: 6065	29-Dec-10 (No. H3-6065_Dec10)	Dec-11
DAE4	SN: 781	20-Oct-10 (No. DAE4-781_Oct10)	Oct-11
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Power sensor HP 8482H	SN: 3318A09450	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-10)	In house check: Oct-11
RF generator E4433B	MY 41000675	03-Nov-04 (in house check Oct-09)	In house check: Oct-11

Calibrated by: **Claudio Leubler** (Name), **Laboratory Technician** (Function), *[Signature]* (Signature)

Approved by: **Katja Pokovic** (Name), **Technical Manager** (Function), *[Signature]* (Signature)

Issued: February 23, 2011

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 74 of 88



Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

References

- [1] ANSI-C63.19-2007
American National Standard for Methods of Measurement of Compatibility between Wireless
Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- *Coordinate System:* y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm above the top edge of the dipole arms.
- *Measurement Conditions:* Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- *Antenna Positioning:* The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- *Feed Point Impedance and Return Loss:* These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminated by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- *E-field distribution:* E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- *H-field distribution:* H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 75 of 88

1. Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.6.1 (408)
DASY PP Version	SEMCAD X	V14.4.2 (2595)
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 90 mm
Frequency	1880 MHz ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

2. Maximum Field values

H-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured	100 mW forward power	0.460 A/m

Uncertainty for H-field measurement: 8.2% (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW forward power	139.0 V/m
Maximum measured above low end	100 mW forward power	134.5 V/m
Averaged maximum above arm	100 mW forward power	136.8 V/m

Uncertainty for E-field measurement: 12.8% (k=2)

3. Appendix

3.1 Antenna Parameters

Frequency	Return Loss	Impedance
1730 MHz	23.0 dB	(49.6 + j7.1) Ohm
1880 MHz	21.2 dB	(51.1 + j8.7) Ohm
1900 MHz	21.8 dB	(53.3 + j7.7) Ohm
1950 MHz	28.1 dB	(54.1 – j0.2) Ohm
2000 MHz	20.5 dB	(41.4 – j0.8) Ohm



3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

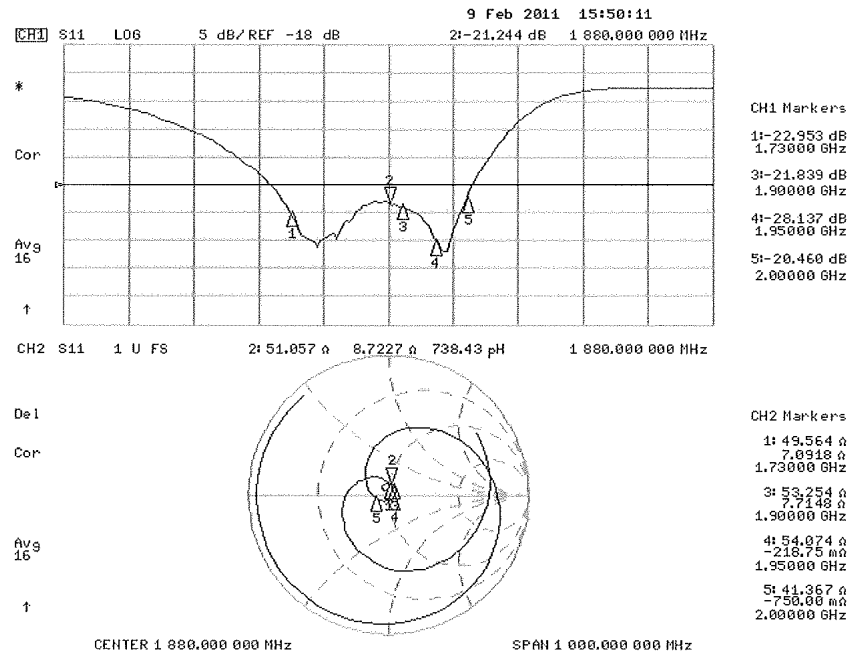
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 76 of 88	

3.3 Measurement Sheets

3.3.1 Return Loss and Smith Chart



FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 77 of 88

3.3.2 DASY4 H-Field Result

Date/Time: 09.02.2011 11:34:28

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1137_H_110208_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1880 MHz

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IBEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole H-Field measurement @ 1880MHz/H Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.460 A/m

Probe Modulation Factor = 1.000

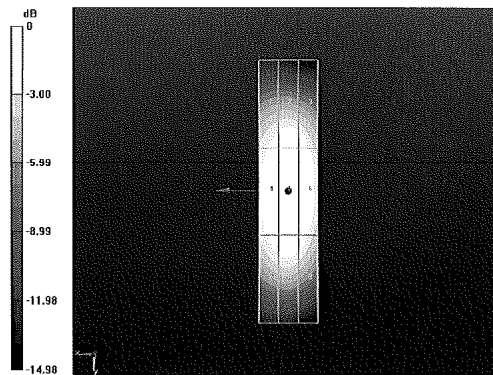
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.487 A/m; Power Drift = 0.0057 dB



Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.401 M2	Grid 2 0.418 M2	Grid 3 0.396 M2
Grid 4 0.443 M2	Grid 5 0.460 M2	Grid 6 0.435 M2
Grid 7 0.409 M2	Grid 8 0.426 M2	Grid 9 0.399 M2



0 dB = 0.460A/m

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 78 of 88

3.3.3 DASY4 E-Field Result

Date/Time: 08.02.2011 16:54:42

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1137_E_110208_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1880 MHz

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole E-Field measurement @ 1880MHz/E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 139.0 V/m

Probe Modulation Factor = 1.000

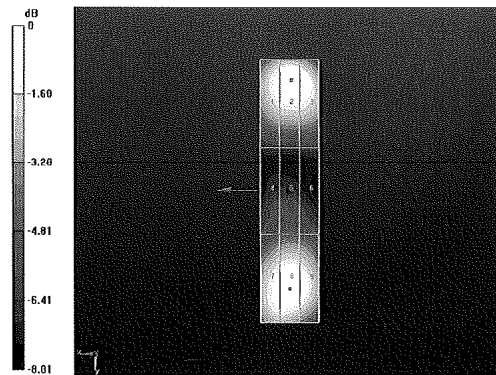
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 138.8 V/m; Power Drift = -0.05 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 131.8 M2	Grid 2 139.0 M2	Grid 3 135.0 M2
Grid 4 84.076 M3	Grid 5 87.648 M3	Grid 6 85.767 M3
Grid 7 131.1 M2	Grid 8 134.5 M2	Grid 9 130.5 M2



0 dB = 139.0V/m

Certificate No: CD1880V3-1137_Feb11/2

Page 6 of 9

FCC ID: A3LSCHI415	PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 79 of 88	

4. Additional Measurements

4.1 Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.6.1 (408)
DASY PP Version	SEMCAD X	V14.4.2 (2595)
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 90 mm
Frequency	1730 MHz ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	



4.1.1 Maximum Field values

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW forward power	0.489 A/m

Uncertainty for H-field measurement: 8.2% (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW forward power	152.7 V/m
Maximum measured above low end	100 mW forward power	150.2 V/m
Averaged maximum above arm	100 mW forward power	151.5 V/m

Uncertainty for E-field measurement: 12.8% (k=2)

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 SAMSUNG	Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 80 of 88

4.1.2 DASYS4 H-field result

Date/Time: 09.02.2011 11:27:03

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1137_H_1730_110208_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1730 MHz

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASYS5 (IEEE/IEC/ANSI C63.19-2007)

DASYS5 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASYS2, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole H-Field measurement @ 1880MHz/H Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm @ 1730 MHz/Hearing Aid Compatibility Test (41x181x1);

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.489 A/m

Probe Modulation Factor = 1.000

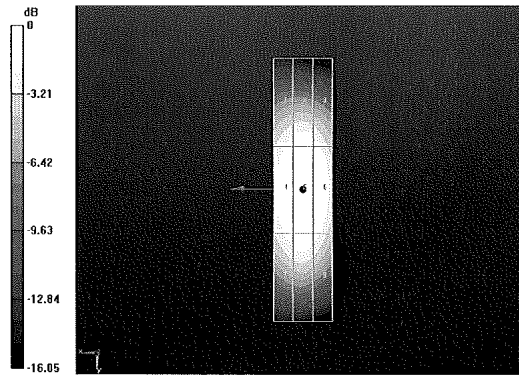
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.519 A/m; Power Drift = 0.02 dB



Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.407 M2	Grid 2 0.424 M2	Grid 3 0.403 M2
Grid 4 0.467 M2	Grid 5 0.489 M2	Grid 6 0.462 M2
Grid 7 0.418 M2	Grid 8 0.437 M2	Grid 9 0.409 M2



0 dB = 0.490A/m

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT	 SAMSUNG	Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 81 of 88	

4.1.3 DASY4 E-field result

Date/Time: 08.02.2011 16:26:13

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1137_E_1730_110208_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1730 MHz

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IBEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole E-Field measurement @ 1880MHz/E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm @ 1730 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 152.7 V/m

Probe Modulation Factor = 1.000

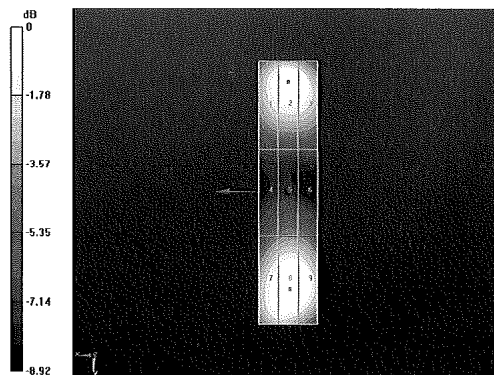
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 156.8 V/m; Power Drift = 0.0092 dB



Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 143.8 M2	Grid 2 150.2 M2	Grid 3 144.8 M2
Grid 4 97.621 M3	Grid 5 103.8 M3	Grid 6 102.2 M3
Grid 7 145.9 M2	Grid 8 152.7 M2	Grid 9 149.2 M2





0 dB = 152.7V/m

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset		Page 82 of 88

15. CONCLUSION



The measurements taken in accordance with the procedures provided in the CTIA Test Plan for Hearing Aid Compatibility Rev 2.0, April 2010, indicate that the wireless communications device complies with the HAC limits specified in the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.



FCC ID: A3LSCHI415		HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: 0Y1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 83 of 88	

16. REFERENCES

1. ANSI/IEEE C63.19-2007, "American National Standard for Methods of Measurement of Compatibility between Wireless Communication Devices and Hearing Aids.", New York, NY, IEEE, June 2007
2. CTIA Test Plan for Hearing Aid Compatibility, Revision 2.0, April 2010.
3. FCC Public Notice DA 06-1215, *Wireless Telecommunications Bureau and Office of Engineering and Technology Clarify Use of Revised Wireless Phone Hearing Aid Compatibility Standard*, June 6, 2006
4. Review Guidance for Reviewing Applications for Certification of 3G Devices, May/June 2006
5. Berger, H. S., "Compatibility Between Hearing Aids and Wireless Devices," Electronic Industries Forum, Boston, MA, May, 1997
6. Berger, H. S., "Hearing Aid and Cellular Phone Compatibility: Working Toward Solutions," *Wireless Telephones and Hearing Aids: New Challenges for Audiology*, Gallaudet University, Washington, D.C., May, 1997 (To be reprinted in the American Journal of Audiology).
7. Berger, H. S., "Hearing Aid Compatibility with Wireless Communications Devices," IEEE International Symposium on Electromagnetic Compatibility, Austin, TX, August, 1997.
8. Bronaugh, E. L., "Simplifying EMI Immunity (Susceptibility) Tests in TEM Cells," in the 1990 IEEE International Symposium on Electromagnetic Compatibility Symposium Record, Washington, D.C., August 1990, pp. 488-491
9. Byrne, D. and Dillon, H., The National Acoustics Laboratory (NAL) New Procedure for Selecting the Gain and Frequency Response of a Hearing Aid, *Ear and Hearing* 7:257-265, 1986.
10. Crawford, M. L., "Measurement of Electromagnetic Radiation from Electronic Equipment using TEM Transmission Cells," U.S. Department of Commerce, National Bureau of Standards, NBSIR 73-306, Feb. 1973.
11. Crawford, M. L., and Workman, J. L., "Using a TEM Cell for EMC Measurements of Electronic Equipment," U.S. Department of Commerce, National Bureau of Standards. Technical Note 1013, July 1981.
12. EHIMA GSM Project, Development phase, Project Report (1st part) Revision A. Technical-Audiological Laboratory and Telecom Denmark, October 1993.
13. EHIMA GSM Project, Development phase, Part II Project Report. Technical-Audiological Laboratory and Telecom Denmark, June 1994.
14. EHIMA GSM Project Final Report, Hearing Aids and GSM Mobile Telephones: Interference Problems, Methods of Measurement and Levels of Immunity. Technical-Audiological Laboratory and Telecom Denmark, 1995.
15. HAMPIS Report, Comparison of Mobile phone electromagnetic near field with an upscaled electromagnetic far field, using hearing aid as reference, 21 October 1999.

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 84 of 88	

16. Hearing Aids/GSM, Report from OTWIDAM, Technical-Audiological Laboratory and Telecom Denmark, April 1993.
17. IEEE 100, The Authoritative Dictionary of IEEE Standards Terms, Seventh Edition.
18. Joyner, K. H., et. al., Interference to Hearing Aids by the New Digital Mobile Telephone System, Global System for Mobile (GSM) Communication Standard, National Acoustic Laboratory, Australian Hearing Series, Sydney 1993.
19. Joyner, K. H., et. al., Interference to Hearing Aids by the Digital Mobile Telephone System, Global System for Mobile Communications (GSM), NAL Report #131, National Acoustic Laboratory, Australian Hearing Series, Sydney, 1995.
20. Kecker, W. T., Crawford, M. L., and Wilson, W. A., "Construction of a Transverse Electromagnetic Cell", U.S. Department of Commerce, National Bureau of Standards, Technical Note 1011, Nov. 1978.
21. Konigstein, D., and Hansen, D., "A New Family of TEM Cells with enlarged bandwidth and Optimized working Volume," in the Proceedings of the 7th International Symposium on EMC, Zurich, Switzerland, March 1987; 50:9, pp. 127-132.
22. Kuk, F., and Hjorstgaard, N. K., "Factors affecting interference from digital cellular telephones," Hearing Journal, 1997; 50:9, pp 32-34.
23. Ma, M. A., and Kanda, M., "Electromagnetic Compatibility and Interference Metrology," U.S. Department of Commerce, National Bureau of Standards, Technical Note 1099, July 1986, pp. 17-43.
24. Ma, M. A., Sreenivashiah, I., and Chang, D. C., "A Method of Determining the Emission and Susceptibility Levels of Electrically Small Objects Using a TEM Cell," U.S. Department of Commerce, National Bureau of Standards, Technical Note 1040, July 1981.
25. McCandless, G. A., and Lyregaard, P. E., Prescription of Gain/Output (POGO) for Hearing Aids, Hearing Instruments 1:16-21, 1983
26. Skopec, M., "Hearing Aid Electromagnetic Interference from Digital Wireless Telephones," IEEE Transactions on Rehabilitation Engineering, vol. 6, no. 2, pp. 235-239, June 1998.
27. Technical Report, GSM 05.90, GSM EMC Considerations, European Telecommunications Standards Institute, January 1993.
28. Victorian, T. A., "Digital Cellular Telephone Interference and Hearing Aid Compatibility—an Update," Hearing Journal 1998; 51:10, pp. 53-60
29. Wong, G. S. K., and Embleton, T. F. W., eds., AIP Handbook of Condenser Microphones: Theory, Calibration and Measurements, AIP Press.

FCC ID: A3LSCHI415	 PCTEST ENGINEERING LABORATORY, INC.	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
HAC Filename: OY1205290740.A3L	Test Dates: June 19-25, 2012	EUT Type: Portable Handset	Page 85 of 88	